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***HY15P41***  
**Datasheet**

8-Bit RISC-like Mixed Signal Microcontroller  
Embedded 24-Bit  $\Sigma\Delta$ ADC

**Table of Contents**

<b>1. FEATURES .....</b>	<b>5</b>
<b>2. PIN DEFINITION .....</b>	<b>6</b>
2.1. Pin Description .....	7
2.2. Package marking information .....	11
<b>3. APPLICATION CIRCUIT.....</b>	<b>13</b>
3.1. 3*PIR application (Pyro-electric infrared detector).....	13
3.2. Smart Pressure sensor application .....	13
3.3. Battery voltage, current and temperature detection application .....	13
<b>4. FUNCTION OUTLINE .....</b>	<b>14</b>
4.1. Internal Block Diagram.....	14
4.2. Related Description and Supporting Document.....	14
4.3. Clock System .....	15
4.4. Reset.....	16
4.5. Power System .....	17
4.6. ΣΔADC Network.....	18
4.7. GPIO System .....	19
4.8. Watch Dog System .....	19
4.9. 8-bit Timer A1 System .....	20
4.10. 16-bit Timer B System.....	20
4.11. EUART System .....	21
4.12. I <sup>2</sup> C System .....	23
<b>5. REGISTER LIST .....</b>	<b>24</b>

<b>6. ELECTRICAL CHARACTERISTICS .....</b>	<b>26</b>
6.1. Recommended Operating Conditions.....	26
6.2. Internal RC Oscillator .....	26
6.3. Supply current into VDD excluding peripherals current.....	28
6.4. Port4.....	30
6.5. Rest(Brownout) .....	31
6.6. Power System .....	32
6.7. ΣΔADC, Power Supply and recommended operating conditions .....	34
6.8. Build-In EPROM(BIE).....	40
<b>7. ORDERING INFORMATION.....</b>	<b>41</b>
<b>8. PACKAGE INFORMATION.....</b>	<b>42</b>
8.1. SOP8(S008).....	42
8.2. SOP16(S016).....	46
8.3. DFN12(AS12).....	49
<b>9. REVISION RECORD.....</b>	<b>51</b>

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## 1. Features

- 8-Bit RISC-like microcontrollers with 66 high-performance instruction set H08C (same as H08A)
- 22-Bit ΣΔADC
  - The comb filter uses a 2- order design, Conversion frequency of 7.8Ksps
  - Sampling frequency 500KHz
  - Settable over-sampling rate is 64~32768
  - Fully differential signal input
  - Zero point bias translation controller
  - Signal amplification x1/4,x1/2,x1,x2,x4,x8,x16
  - The measurement signal supports multi-channel input
  - low temperature drift coefficient
  - Built-in absolute temperature sensor
- Internal power supply system
  - Built-in LDO linear regulated power supply VDDA
    - ◆ Internal analog circuit or external sensor voltage source
    - ◆ Multi-stage output voltage can be set to external input voltage
    - ◆ Low operating power consumption and Low temperature drift coefficient
- Timer
  - Watch Dog
    - ◆ Reset event
    - ◆ Interrupt event
  - 8-bit Timer
    - ◆ Interrupt event
- Compare events
- 16-bit Timer
- 16-Bit PWM output
- Two 8-Bit PWM output
- Interrupt event
- Operating voltage and operating temperature range
  - V<sub>DD</sub> : 2.2V ~ 5.5V
  - V<sub>DDA</sub> : 2.4V ~ 4.5V
  - - 40°C ~ 85°C
- Operating frequency
  - Built-in high-precision HAO oscillator (2MHz/4MHz/8MHz)
  - Built-in low power consumption LPO oscillator (14.5KHz)
- Memory
  - 2K word OTP program memory
  - 128 byte data memory
  - 6-layer stack
  - Build-In EPROM
    - ◆ VPP external burning voltage 8.5V
    - ◆ 64 word EPROM memory
- Pin features
  - With 10mA drive capability
- Reset
  - Power On Reset
  - Brown Out Reset
  - Watch Dog Reset
  - Stack Over Reset
- Serial communication EUART module
- I<sup>2</sup>C communication (Master/Slave mode) module
- Package Type
  - SOP8、DFN12、SOP16

## Function list

Model No.	VDD	System Clock (Hz)	Program Memory (word)	SRAM (byte)	BIE (word)	ADC ENOB (bit x ch)	Sample Rate (sps)	TPS	I/O	Timer (bit x ch)	PWM (bit x ch)	Serial Interface (I/F x ch)	Package
HY15P41	2.2V~5.5V	14.5K~8M	2K	128	64	18-bit x 5	15~7.8K	yes	1xI + 5xIO	8-bit x 1 16-bit x 1	8-bit x 2 16-bit x 1	EUART x 1 I <sup>2</sup> C x 1	SOP8 SOP16 DFN12

# HY15P41

Embedded 24-Bit  $\Sigma\Delta$ ADC

8-Bit RISC-like Mixed Signal Microcontroller

## 2. Pin Definition

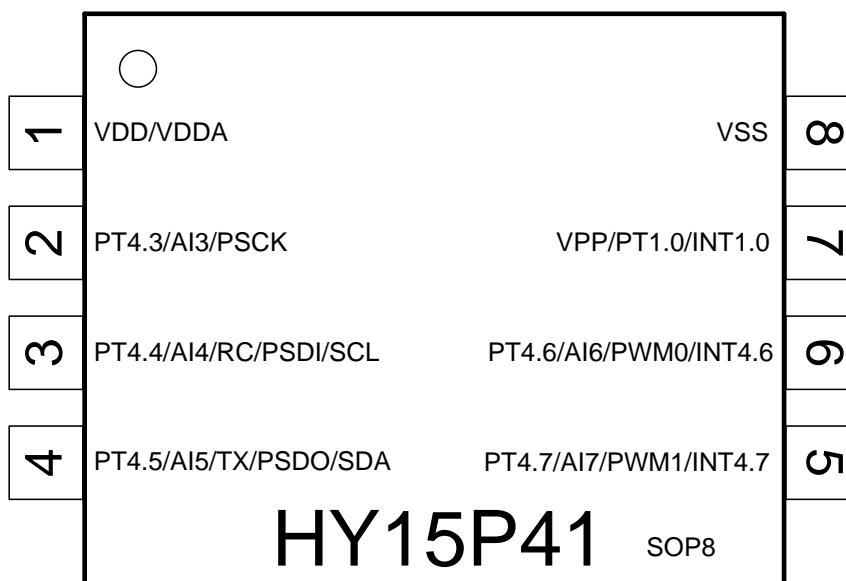


Figure 2-1 HY15P41 SOP8 Diagram

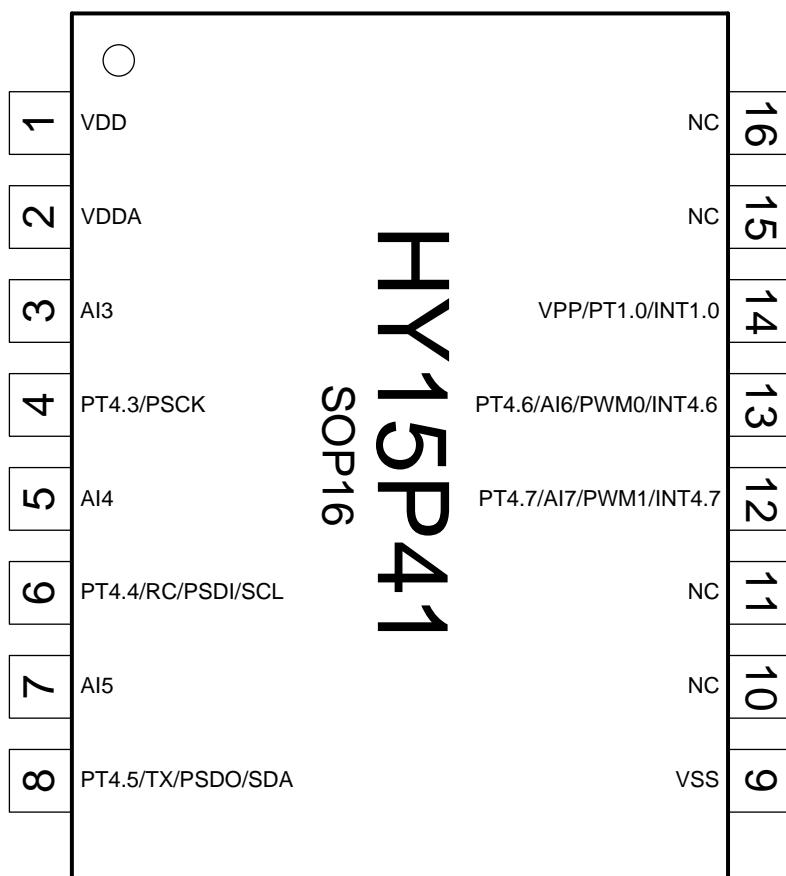


Figure 2-2 HY15P41 SOP16 Diagram

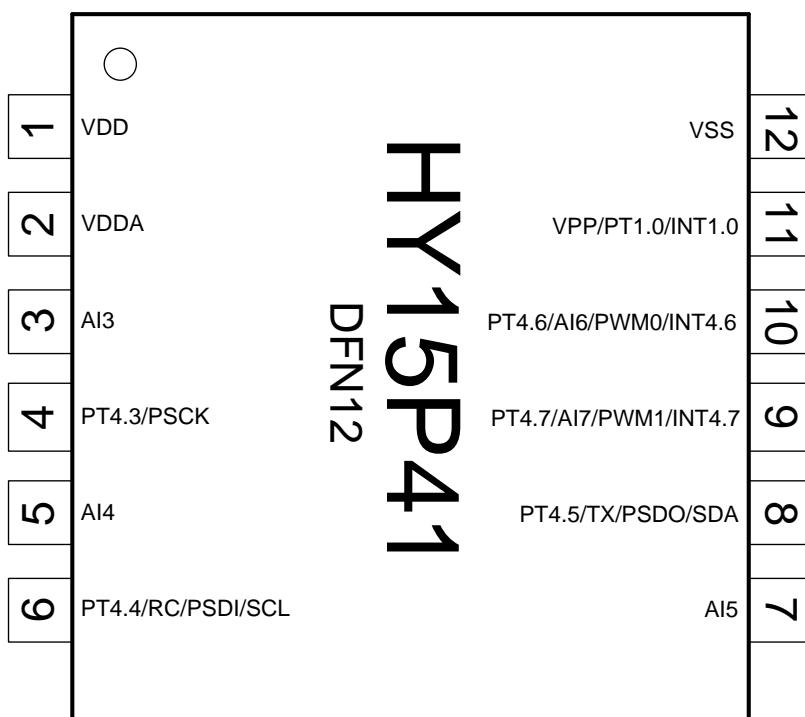


Figure 2-3 HY15P41 DFN12 Diagram

## 2.1. Pin Description

### 2.1.1. SOP8 description

"I" : Input , "O" : Output, "A" : Analog, "S" : Smith triggers, "C" : CMOS I/O, "P" : Power Source, "/" : or , "X" : Ignorable

Package	Pin name	Design		Description
		Type	Buffer	
1	VDD	P	P	Power input for system.
	VDDA	P	P	LDO linear regulated power supply output pin
2	PT4.3	I/O	S/C	Digital input / Output pin
	AI3	A	A	Analog input channel
	PSCK	I	S	OTP read / write interface PSCK interface
3	PT4.4	I/O	C	Digital input / Output pin
	AI4	A	A	Analog input channel
	RC	I	S	RC pin of EUART interface
	PSDI	I	S	OTP read / write interface PSDI interface
	SCL	I/O	S	I <sup>2</sup> C communication clock pin
4	PT4.5	I/O	C	Digital input / Output pin
	AI5	A	A	Analog input channel
	TX	O	S	TX pin of EUART interface

# HY15P41

## Embedded 24-Bit ΣΔADC

8-Bit RISC-like Mixed Signal Microcontroller



Package SOP8	Pin name	Design		Description
		Type	Buffer	
	PSDO	I/O	S	OTP read / write interface PSDO interface
	SDA	I/O	S	I <sup>2</sup> C communication data pin
5	PT4.7	I/O	C	Digital input / Output pin
	AI7	A	A	Analog input channel
	PWM1	O	C	TMB PWM1 output pin
	INT4.7	I	S	External interrupt source
6	PT4.6	I/O	C	Digital input / Output pin
	AI6	A	A	Analog input channel
	PWM0	O	C	TMB PWM0 output pin
	INT4.6	I	S	External interrupt source
7	PT1.0	I	S	Digital input
	VPP	P	P	OTP burning voltage source input pin
	INT1.0	I	S	External interrupt source
8	VSS	P	P	System Power Ground

Table 2-1 SOP8 definition and description

### 2.1.2. SOP16 description

"I" : Input , "O" : Output, "A" : Analog, "S" : Smith triggers, "C" : CMOS I/O,"P" : Power Source,"/" : or , "X" : Ignorable

Package	Pin name	Design		Description
		Type	Buffer	
1	VDD	P	P	Power input for system.
2	VDDA	P	P	LDO linear regulated power supply output pin
3	AI3	A	A	Analog input channel
4	PT4.3	I/O	S/C	Digital input / Output pin
	PSCK	I	S	OTP read / write interface PSCK interface
5	AI4	A	A	Analog input channel
6	PT4.4	I/O	C	Digital input / Output pin
	RC	I	S	RC pin of EUART interface
	PSDI	I	S	OTP read / write interface PSDI interface
	SCL	I/O	S	I <sup>2</sup> C communication clock pin
7	A15	A	A	Analog input channel
8	PT4.5	I/O	C	Digital input / Output pin
	TX	O	S	TX pin of EUART interface
	PSDO	I/O	S	OTP read / write interface PSDO interface
	SDA	I/O	S	I <sup>2</sup> C communication data pin
9	VSS	P	P	System Power Ground
12	PT4.7	I/O	C	Digital input / Output pin
	A17	A	A	Analog input channel
	PWM1	O	C	TMB PWM1 output pin
	INT4.7	I	S	External interrupt source
13	PT4.6	I/O	C	Digital input / Output pin
	AI6	A	A	Analog input channel
	PWM0	O	C	TMB PWM0 output pin
	INT4.6	I	S	External interrupt source
14	PT1.0	I	S	Digital input
	VPP	P	P	OTP burning voltage source input pin
	INT1.0	I	S	External interrupt source
Others	NC	-	-	Not Connect

Table 2-2 SOP16 definition and description

### 2.1.3. DFN12 description

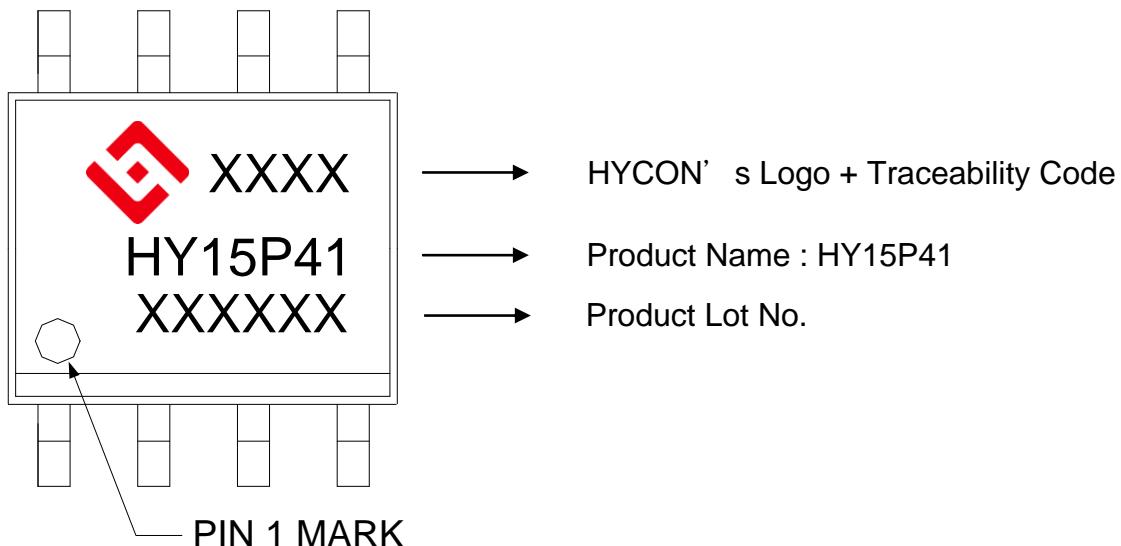
"I" : Input , "O" : Output, "A" : Analog, "S" : Smith triggers, "C" : CMOS I/O,"P" : Power Source,"/" : or , "X" : Ignorable

Package	Pin name	Design		Description
		Type	Buffer	
1	VDD	P	P	Power input for system.
2	VDDA	P	P	LDO linear regulated power supply output pin
3	AI3	A	A	Analog input channel
4	PT4.3	I/O	S/C	Digital input / Output pin
	PSCK	I	S	OTP read / write interface PSCK interface
5	AI4	A	A	Analog input channel
6	PT4.4	I/O	C	Digital input / Output pin
	RC	I	S	RC pin of EUART interface
	PSDI	I	S	OTP read / write interface PSDI interface
	SCL	I/O	S	I <sup>2</sup> C communication clock pin
7	A15	A	A	Analog input channel
8	PT4.5	I/O	C	Digital input / Output pin
	TX	O	S	TX pin of EUART interface
	PSDO	I/O	S	OTP read / write interface PSDO interface
	SDA	I/O	S	I <sup>2</sup> C communication data pin
9	PT4.7	I/O	C	Digital input / Output pin
	AI7	A	A	Analog input channel
	PWM1	O	C	TMB PWM1 output pin
	INT4.7	I	S	External interrupt source
10	PT4.6	I/O	C	Digital input / Output pin
	AI6	A	A	Analog input channel
	PWM0	O	C	TMB PWM0 output pin
	INT4.6	I	S	External interrupt source
11	PT1.0	I	S	Digital input
	VPP	P	P	OTP burning voltage source input pin
	INT1.0	O	S	External interrupt source
12	VSS	P	P	System Power Ground

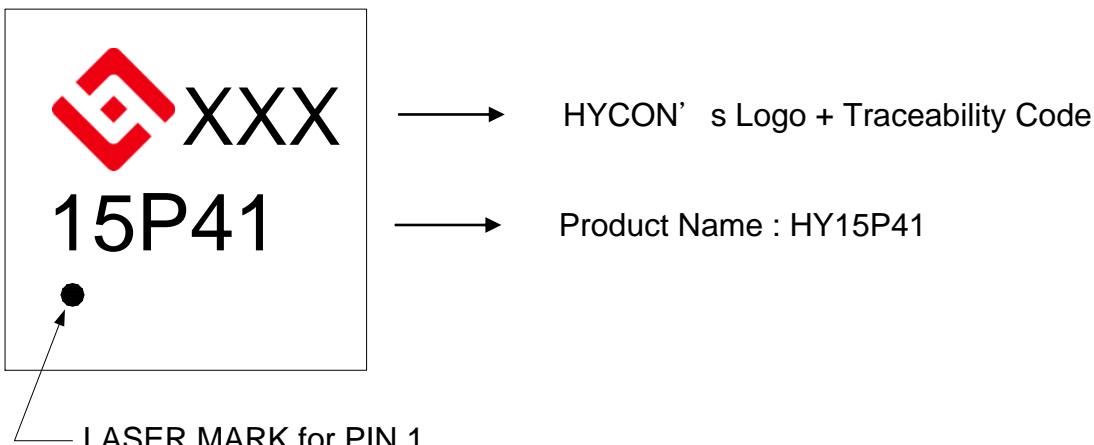
Table 2-3 DFN12 definition and description

## 2.2. Package marking information

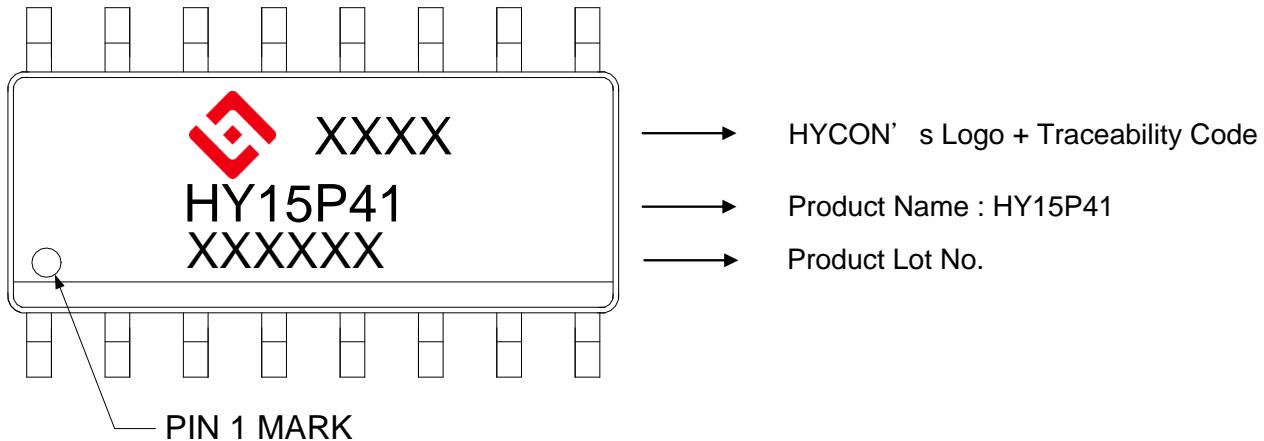
### 2.2.1. SOP8 Package marking information



### 2.2.2. DFN12 Package marking information



#### 2.2.3. SOP16 Package marking information



### 3. Application Circuit

#### 3.1. 3\*PIR application (Pyro-electric infrared detector)

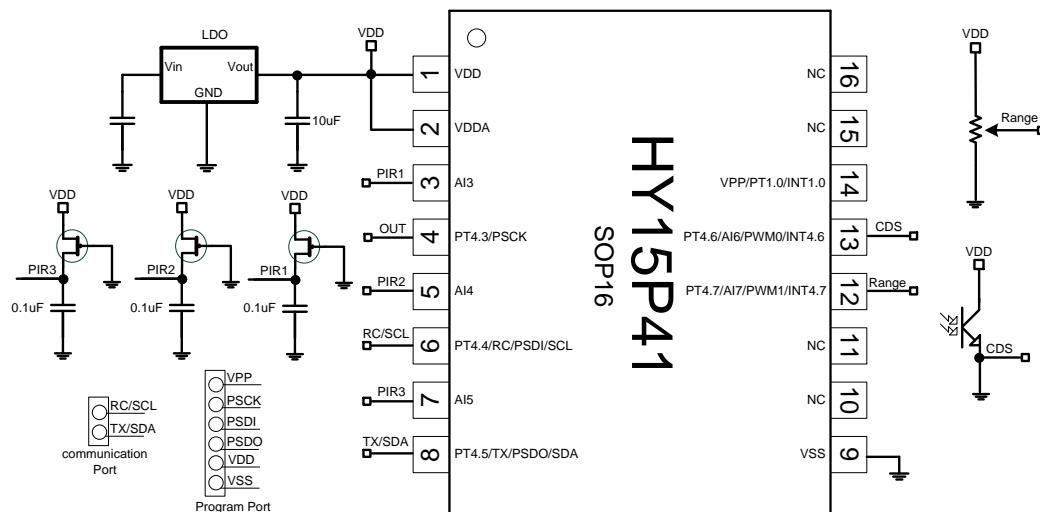


Figure 3-1 3\*PIR application Circuit

#### 3.2. Smart Pressure sensor application

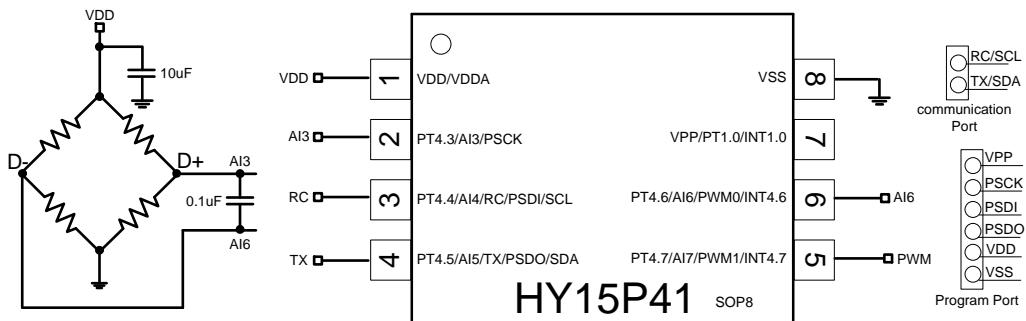


Figure 3-2 Smart Pressure Sensor application Circuit

#### 3.3. Battery voltage, current and temperature detection application

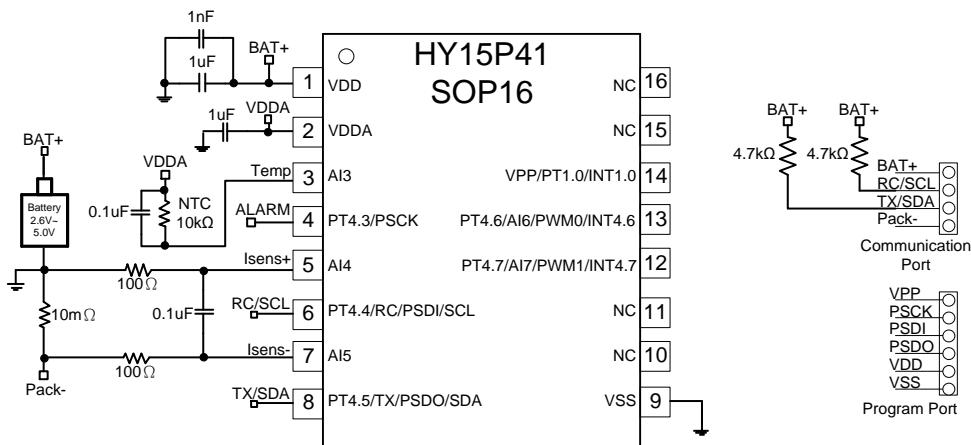


Figure 3-3 Battery voltage, current and temperature detection application Circuit

## 4. Function Outline

### 4.1. Internal Block Diagram

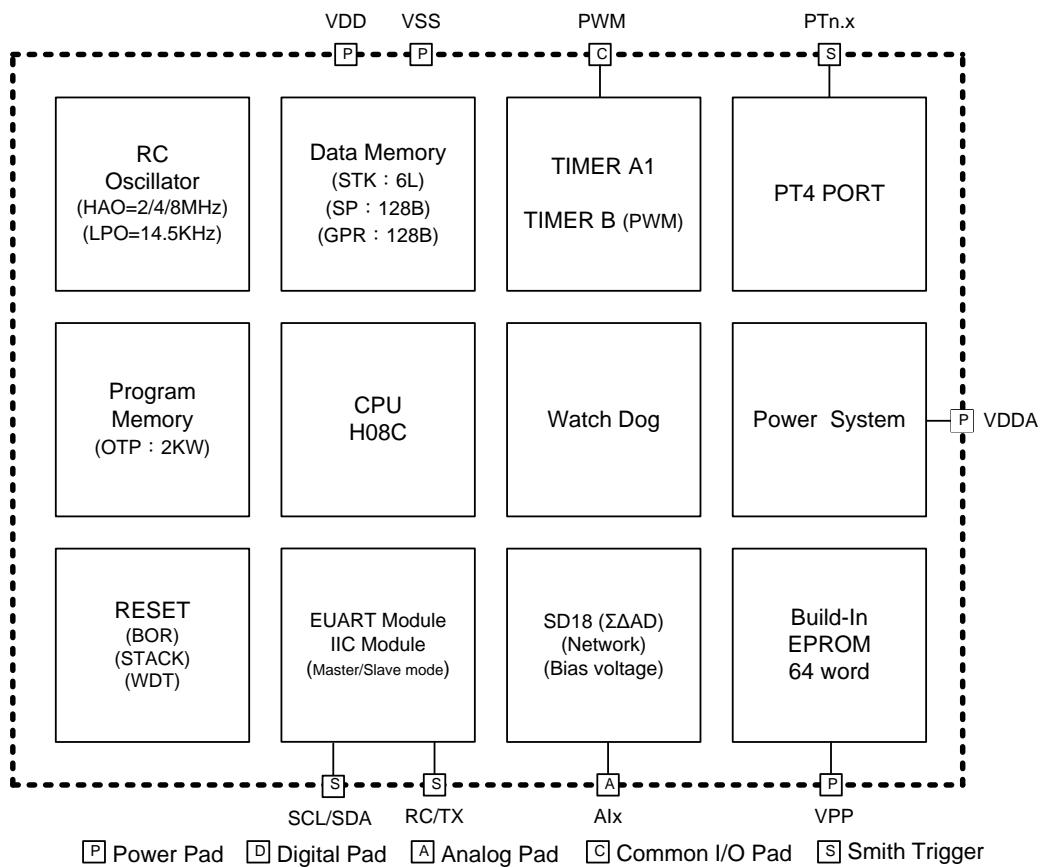


Figure 4-1 HY15P41 Internal Block Diagram

### 4.2. Related Description and Supporting Document

File Name	Description
DS-HY15P41	HY15P41 Datasheet
UG-HY15P41	HY15P41 User's Guide
APD-HYIDE002	HY15P Series development tool software user's manual
APD-HYIDE005	HY15S41 Development tool hardware user's manual
APD-HYIDE003	HY15P Series HexLoader user's manual
APD-HYIDE013	HY10000-WK0XX Integrated writer user's manual
BDI-HY15P41	HY15P41 Bonding information

#### 4.3. Clock System

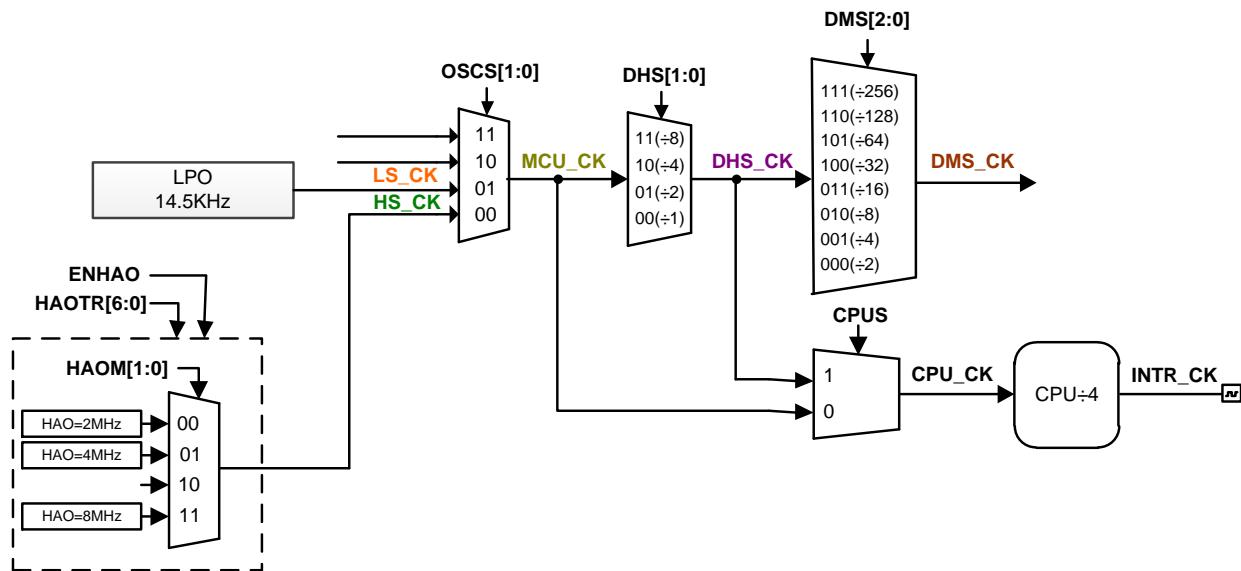


Figure 4-1 Clock System block diagram (1)

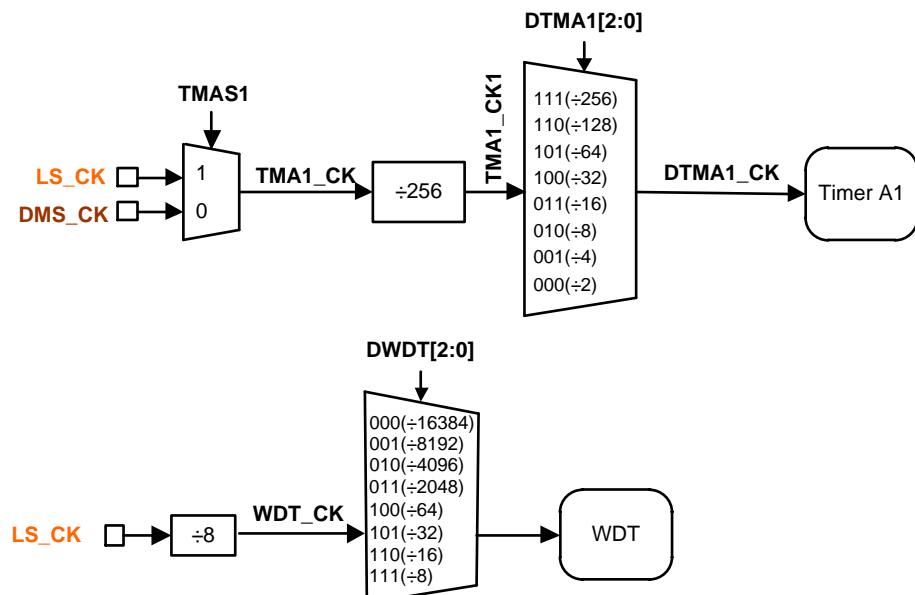


Figure 4-2 Clock System block diagram (2)

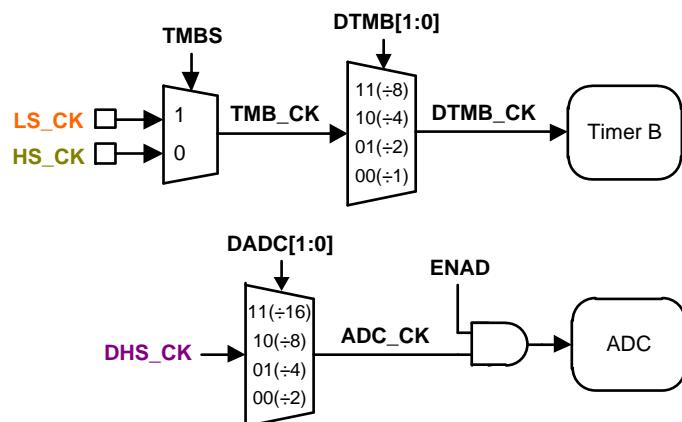


Figure 4-3 Clock System block diagram (3)

#### 4.4. Reset

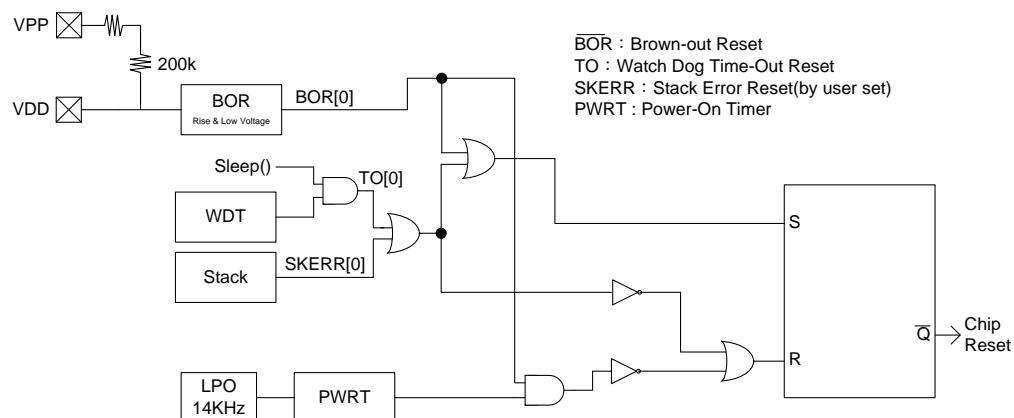


Figure 4-4 Reset block diagram

#### 4.5. Power System

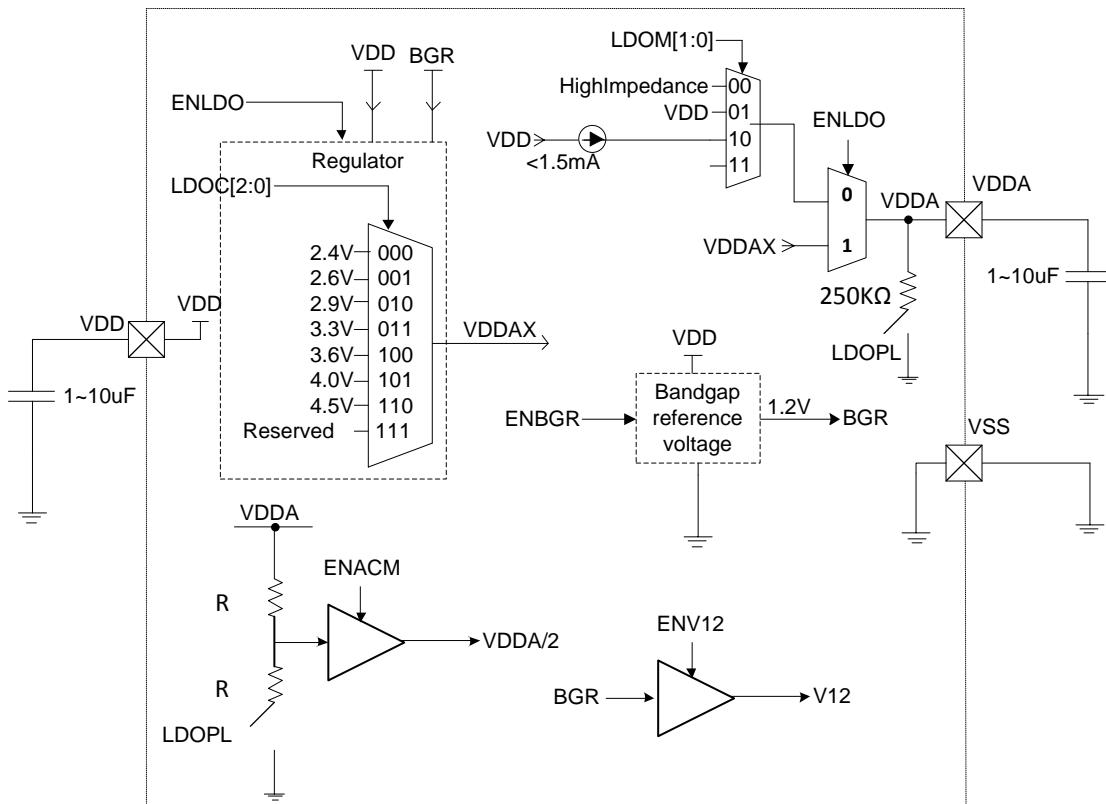


Figure 4-5 Power System block diagram

#### 4.6. $\Sigma\Delta$ ADC Network

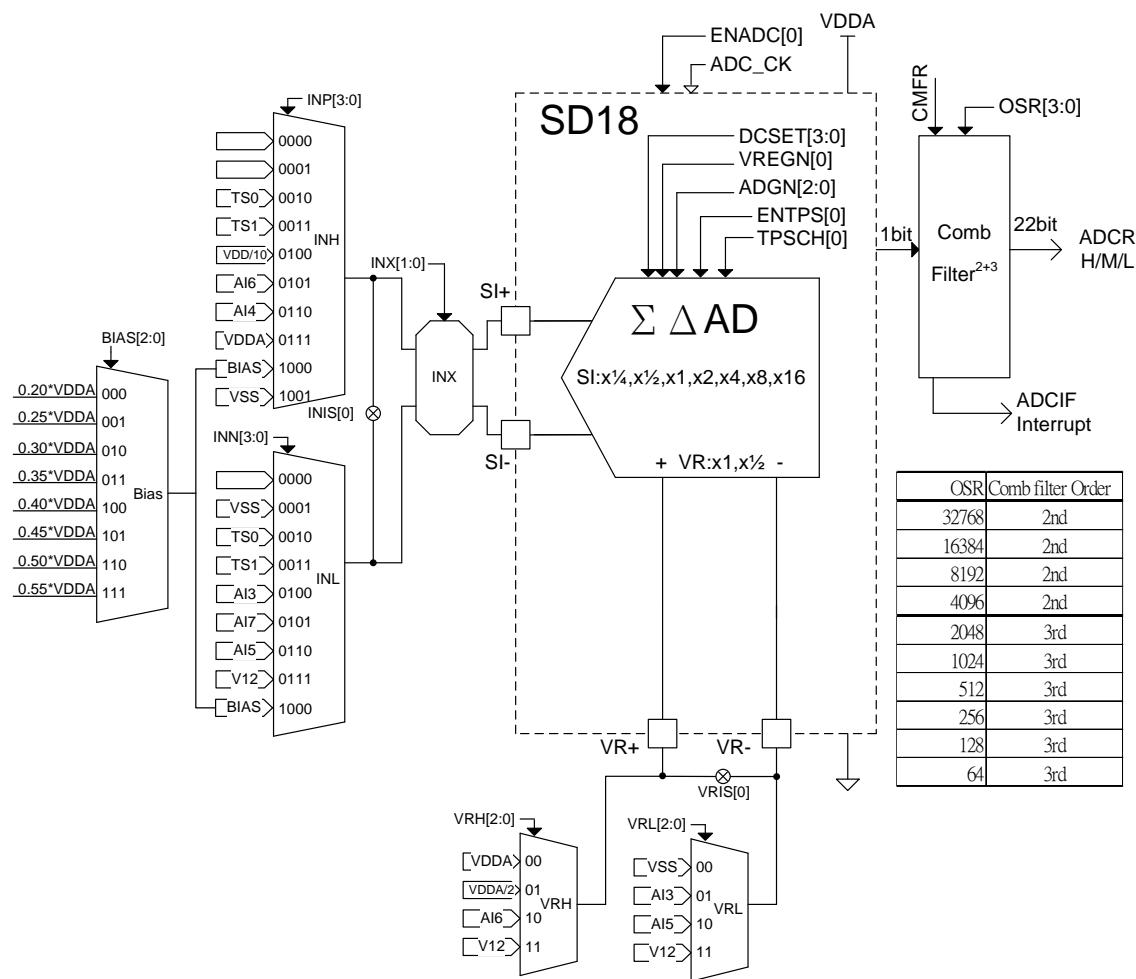


Figure 4-6 SD18 Network

#### 4.7. GPIO System

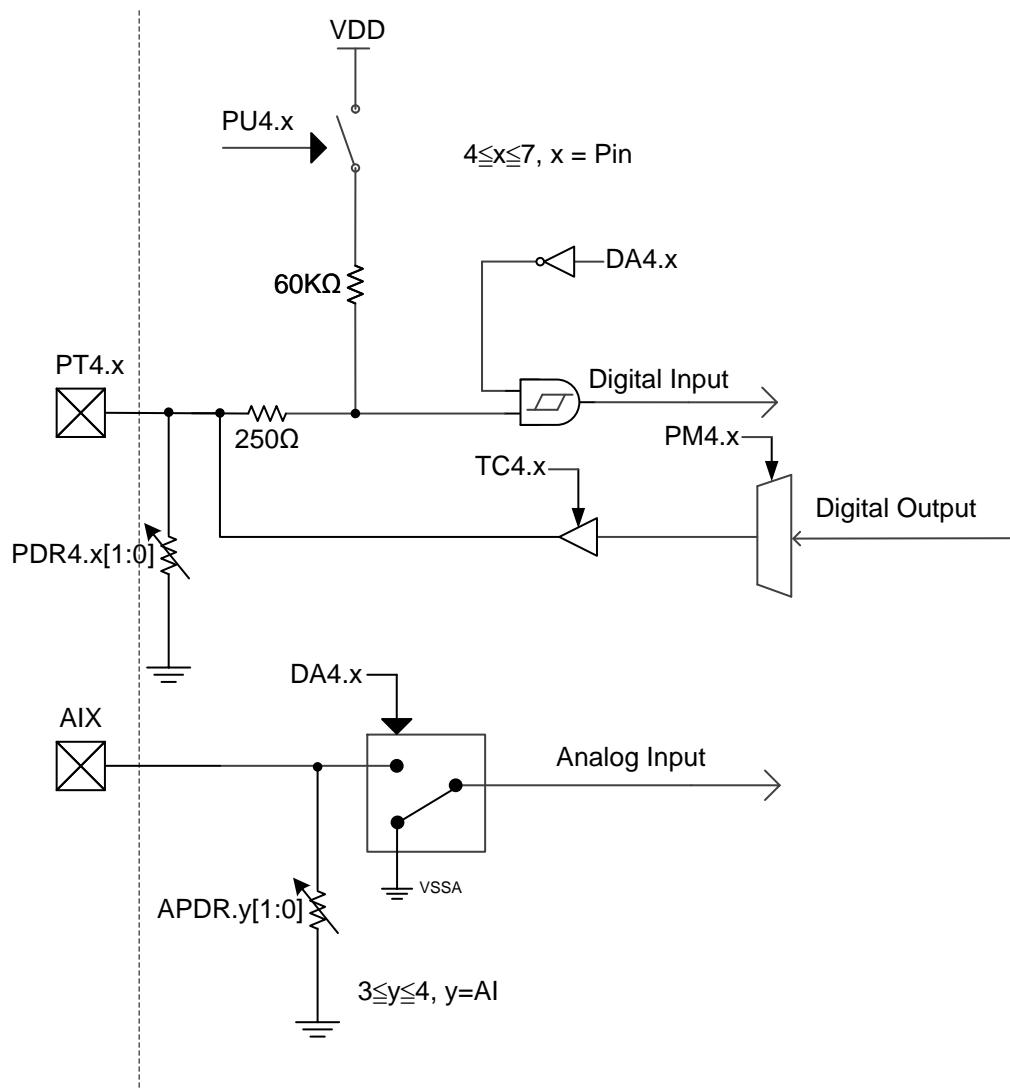


Figure 4-7 GPIO block diagram

#### 4.8. Watch Dog System

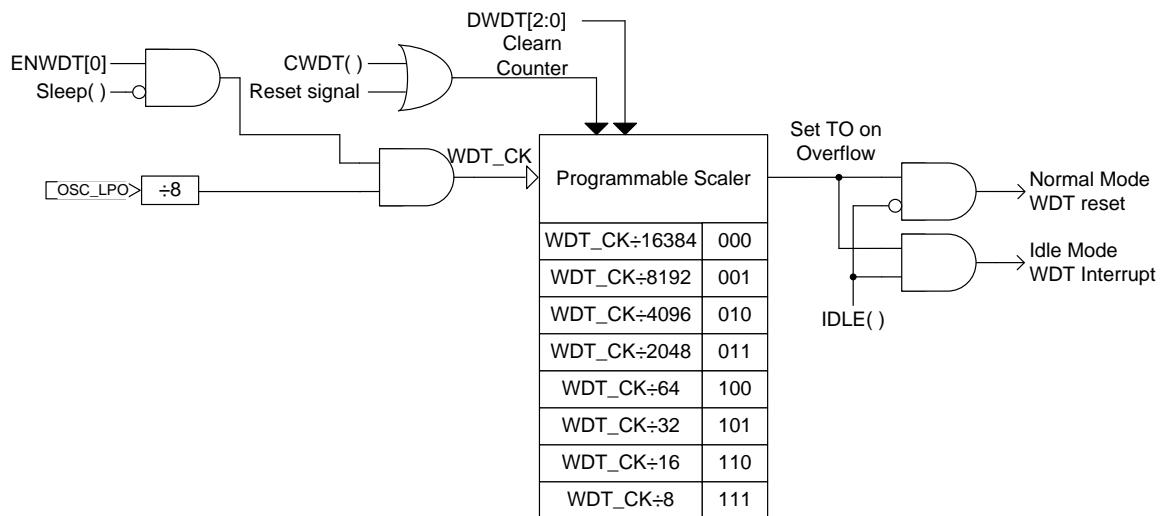


Figure 4-8 Watch Dog block diagram

#### 4.9. 8-bit Timer A1 System

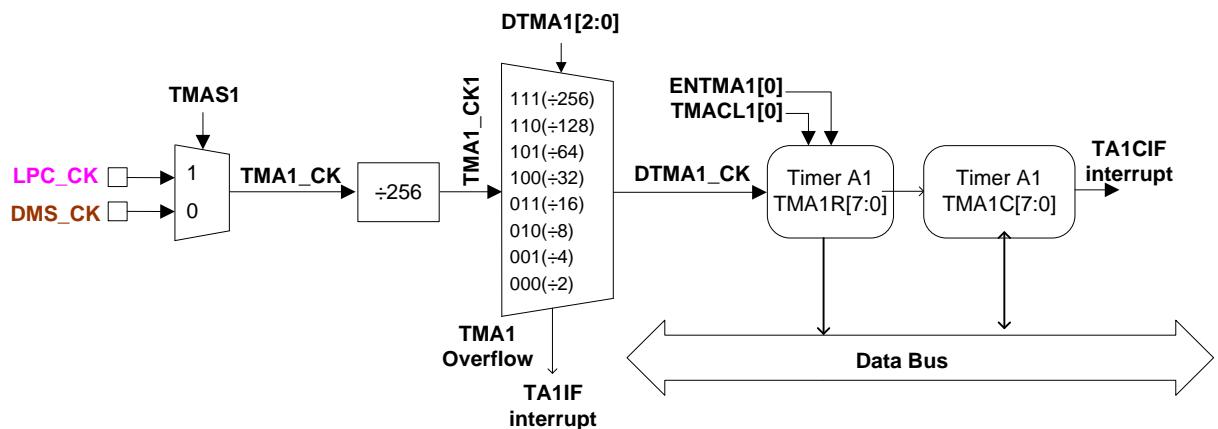


Figure 4-9 8-bit Timer A1 block diagram

#### 4.10. 16-bit Timer B System

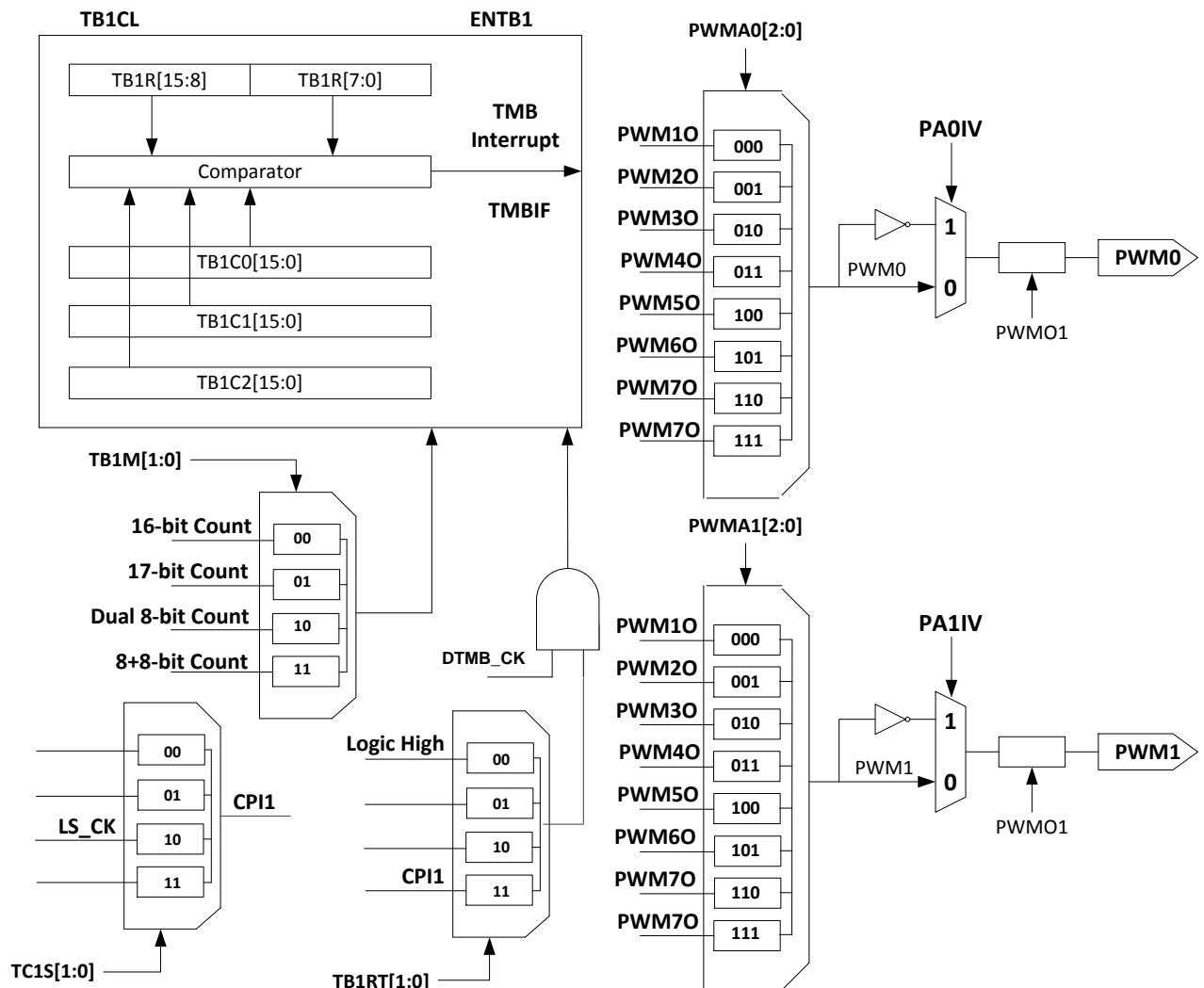


Figure 4-10 16-bit Timer B block diagram

#### 4.11. EUART System

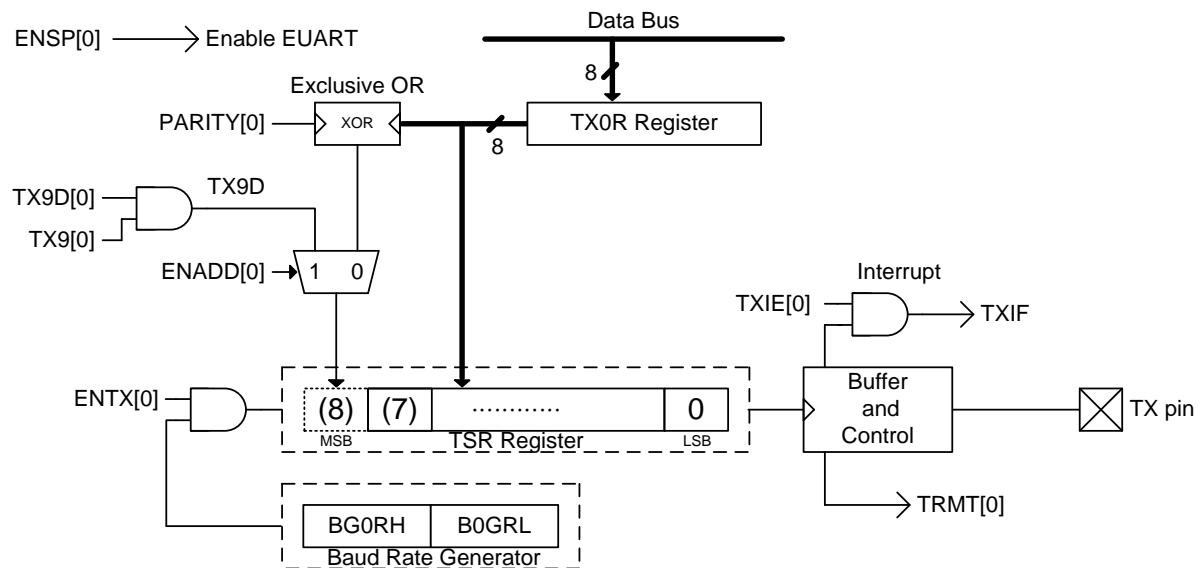
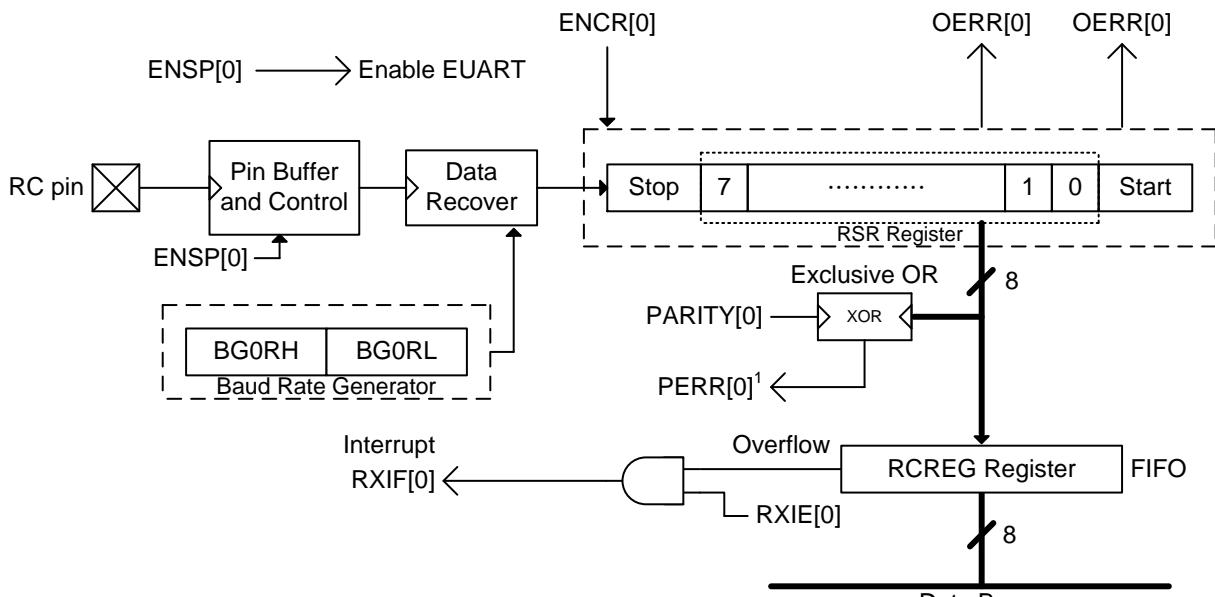


Figure 4-11 EUART transmit block diagram



<sup>1</sup>Don't care PERR[0] state of 8-bits receive mode

Figure 4-12 EUART 8-bits receive block diagram

## 4.12. I<sup>2</sup>C System

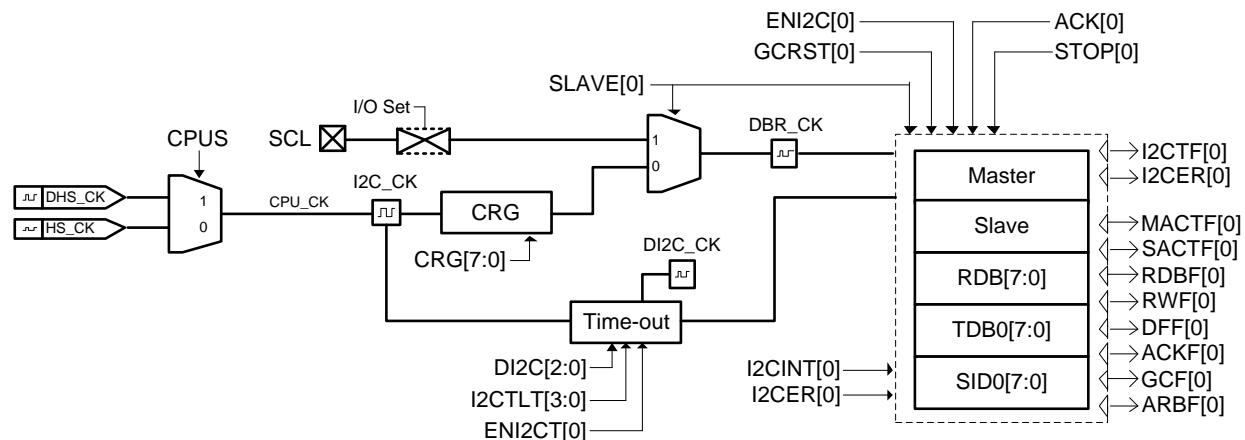


Figure 4-14 I<sup>2</sup>C block diagram

## 5. Register list

--no use, "*"read/write, "w"write, "r"read, "r0"only read 0, "r1"only read 1, "w0"only write 0, "w1"only write 1 "\$"for event status, ".unimplemented bit, "X"unknown, "U"unchanged, "D"depends on condition																			
Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	ARST	IRST	R/W							
000h	INDF0	Contents of FSR0 to address data memory value of FSR0 not changed								xxxx xxxx	uuuu uuuu	*,*,*,*,*,*							
001h	POINCO	Contents of FSR0 to address data memory value of FSR0 post-increment								xxxx xxxx	uuuu uuuu	*,*,*,*,*,*							
002h	PODEC0	Contents of FSR0 to address data memory value of FSR0 post-decrement								xxxx xxxx	uuuu uuuu	*,*,*,*,*,*							
003h	PRINCO	Contents of FSR0 to address data memory value of FSR0 pre-incremented								xxxx xxxx	uuuu uuuu	*,*,*,*,*,*							
004h	PLUSW0	Contents of FSR0 to address data memory value of FSR0 offset by W								xxxx xxxx	uuuu uuuu	*,*,*,*,*,*							
005h	INDF1	Contents of FSR1 to address data memory value of FSR1 not changed								xxxx xxxx	uuuu uuuu	*,*,*,*,*,*							
006h	POINC1	Contents of FSR1 to address data memory value of FSR1 post-increment								xxxx xxxx	uuuu uuuu	*,*,*,*,*,*							
007h	PODEC1	Contents of FSR1 to address data memory value of FSR1 post-decrement								xxxx xxxx	uuuu uuuu	*,*,*,*,*,*							
008h	PRINC1	Contents of FSR1 to address data memory value of FSR1 pre-incremented								xxxx xxxx	uuuu uuuu	*,*,*,*,*,*							
009h	PLUSW1	Contents of FSR1 to address data memory value of FSR1 offset by W								xxxx xxxx	uuuu uuuu	*,*,*,*,*,*							
00Ah	INDF2	Contents of FSR2 to address data memory value of FSR2 not changed								xxxx xxxx	uuuu uuuu	*,*,*,*,*,*							
00Bh	POINC2	Contents of FSR2 to address data memory value of FSR2 post-increment								xxxx xxxx	uuuu uuuu	*,*,*,*,*,*							
00Ch	PODEC2	Contents of FSR2 to address data memory value of FSR2 post-decrement								xxxx xxxx	uuuu uuuu	*,*,*,*,*,*							
00Dh	PRINC2	Contents of FSR2 to address data memory value of FSR2 pre-incremented								xxxx xxxx	uuuu uuuu	*,*,*,*,*,*							
00Eh	PLUSW2	Contents of FSR2 to address data memory value of FSR2 offset by W								xxxx xxxx	uuuu uuuu	*,*,*,*,*,*							
010h	FSR0L	Indirect Data Memory Address Pointer 0 Low Byte,FSR0[7:0]								xxxx xxxx	uuuu uuuu	*,*,*,*,*,*							
012h	FSR1L	Indirect Data Memory Address Pointer 0 Low Byte,FSR1[7:0]								xxxx xxxx	uuuu uuuu	*,*,*,*,*,*							
014h	FSR2L	Indirect Data Memory Address Pointer 0 Low Byte,FSR2[7:0]								xxxx xxxx	uuuu uuuu	*,*,*,*,*,*							
016h	TOSH	-	-	-	-	TOS[11:8]				..xx xxxx	..uu uuuu	-,-,*,*,*,*							
017h	TOSL	Top-of-Stack Low Byte (TOS<7:0>)								xxxx xxxx	uuuu uuuu	*,*,*,*,*,*							
018h	SKCN	SKFL	SKUN	SKOV	-	-	SKPRT[2:0]			000. 0000	u\$\$. \$\$\$\$	rw0,rw0,rw0,-,*,*,*							
01Ah	PCLATH	-	-	-	-	PC[11:8]				.00 0000	.00 0000	*,*,*,*,*,*							
01Bh	PCLATL	PC Low Byte for PC<7:0>								0000 0000	0000 0000	*,*,*,*,*,*							
01Dh	TBLPTRH	-	-	-	-	TBLPTR[11:8]				..xx xxxx	..uu uuuu	-,-,*,*,*,*							
01Eh	TBLPTRL	Program Memory Table Pointer Low Byte (TBLPTR<7:0>)								xxxx xxxx	uuuu uuuu	*,*,*,*,*,*							
01Fh	TBLDH	Program Memory Table Latch High Byte								xxxx xxxx	uuuu uuuu	*,*,*,*,*,*							
020h	TBLDL	Program Memory Table Latch Low Byte								xxxx xxxx	uuuu uuuu	*,*,*,*,*,*							
021h	PRODH	Product Register of Multiply High Byte								xxxx xxxx	uuuu uuuu	*,*,*,*,*,*							
022h	PRODL	Product Register of Multiply Low Byte								xxxx xxxx	uuuu uuuu	*,*,*,*,*,*							
023h	INTE0	GIE	TA1CIE	ADIE	WDTIE	TB1IE			E0IE	0000 0000	0uuu uuuu	*,*,*,*,*,*							
024h	INTE1	TA1IE		TXIE	RCIE	I2CERIE	I2CIE			0000 0000	uuuu uuuu	*,*,*,*,*,*							
026h	INTF0	-	TA1CIF	ADIF	WDTIF	TB1IF			E0IF	.000 0000	.uuu uuuu	*,*,*,*,*,*							
027h	INTF1	TA1IF		TXIF	RCIF	I2CERIF	I2CIF			0000 0000	uuuu uuuu	*,*,* r,r,*,*							
029h	WREG	Working Register								xxxx xxxx	uuuu uuuu	*,*,*,*,*,*							
02Bh	MSTAT	-	-	-	C	DC	N	OV	Z	...x xxxx	...u uuuu	-,-,*,*,*,*							
02Ch	PSTAT	BOR	PD	TO	IDL	-	SKERR	-	-	\$000 \$000	uu\$u u\$u.	rw0,rw0,rw0,rw0,rw0,rw0,rw0,-							
02Eh	BIECN	1	-	-	-	-	-	-	BIEWR	BIERD	1... \$000	1... \$uuu	r1,-,-,r,*,*						
030h	BIEARL	-	-	BIE Address Register as BIEAL[5:0]								xxxx xxxx	uuuu uuuu						
031h	BIEDRH	BIE High Byte Data Register								xxxx xxxx	uuuu uuuu	*,*,*,*,*,*							
032h	BIEDRL	BIE Low Byte Data Register								xxxx xxxx	uuuu uuuu	*,*,*,*,*,*							
033h	PWRCN	ENBGR	LDOC[2:0]		LDOM[0]	LDOM	ENLDO	CSFON		0000 0000	uuuu u00u	*,*,* wr0,wr0,*							
034h	OSCCN0	OSCS[1:0]		DHS[1:0]		DMS[2:0]		CUPS		0000 0000	uuuu uuuu	*,*,*,*,*,*							
035h	OSCCN1	CCOPT		DADC[1:0]		DTMB[1:0]		TMBS	-	0000 0000	uuuu uuuu	*,*,*,*,*,-							
036h	OSCCN2					HAOM[1:0]			ENHAO	0000 0001	uuuu uu01	*,*,*,*,*,*							
037h	WDTCN				ENWDT	DWDT[2:0]				0000 0000	uuuu \$000	-,-,* rw1,*,*							
03Ah	AD1H	ADC1 conversion high byte data register								.00 0000	..uu uuuu	-,-,*,*,*,*							
03Bh	AD1M	ADC1 conversion middle byte data register								0000 0000	uuuu uuuu	*,*,*,*,*,*							
03Ch	AD1L	ADC1 conversion low byte data register						0	0	0000 0000	uuuu uuuu	*,*,*,*,*,*							
03Dh	AD1CN0	ENAD1	-	-	OSR[3:0]			CMFR		000. 0000	uuu. uuuu	*,*,*,*,*,*							
03Eh	AD1CN1	-	-	VREGN		ADGN[2:0]				xxxx xxxx	uuuu uuuu	*,*,*,*,*,*							
03Fh	AD1CN2	-	BIAS[2:0]		DCSET[3:0]					xxxx xxxx	uuuu uuuu	*,*,*,*,*,*							
040h	AD1CN3	INP[3:0]			INN[3:0]					xxxx xxxx	uuuu uuuu	*,*,*,*,*,*							
041h	AD1CN4	VRH[1:0]		VRL[1:0]		INX[1:0]		VRIS	INIS	0010 0000	uuuu uuuu	*,*,*,*,*,*							
042h	AD1CN5	ENACM	ENV12	VCMS	LDOPL	ENBS	-	ENTPS	TPSCH	0000 0000	uuuu uuuu	*,*,*,*,*,*							
043h	CSFCN0	SKRST		HAOTR[6:0]						.1... ....	.... ....	-,-,-,-,-,-							
044h	TMA1CN	ENTMA1	TMACL1	TMAS1	DTMA1[2:0]		-	-		0000 00..	u0uu uu..	*,rw1,*,*,*,-							
045h	TMA1R	TMA1 counter Register								0000 0000	uuuu uuuu	rw0,rw0,rw0,rw0,rw0,rw0,rw0,rw0							
046h	TMA1C	TMA1C counter Register								0000 0000	uuuu uuuu	rw0,rw0,rw0,rw0,rw0,rw0,rw0,rw0							

Table 5-1 Data memory list (1)

# HY15P41

## Embedded 24-Bit ΣΔADC

8-Bit RISC-like Mixed Signal Microcontroller



Data Memory Map																			
Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	ARST	IRST	R/W							
047h	AIXM1	APDR3[1:0]	-	-	-	-	-	-	-	0000 0000	uuuu uuuu	*****							
048h	AIXM2	-	-	-	-	-	-	-	-	0000 0000	uuuu uuuu	*****							
04Eh	TB1Flag	-	-	PWM6A	PWM5A	PWM4A	PWM3A	PWM2A	PWM1A	.00 0000	..uu uuuu	-,-,r,r,r,r,r,r							
04Fh	TB1CN0	ENTB1	TB1M[1:0]	TB1RT[1:0]	TB1CL	-	-	-	-	0000 0000	uuuu u0uu	,*,*,*,rw 1,**							
050h	TB1CN1	PA1IV	PWMA1[2:0]	PA0IV	PWMA0[2:0]					0000 0000	uuuu uuuu	****							
051h	TB1RH	TimerB1 counter Register [15:8]										xxxx xxxx							
052h	TB1RL	TimerB1 counter Register [7:0]										xxxx xxxx							
053h	TB1C0H	TimerB1 counter Condition Register [15:8]										xxxx xxxx							
054h	TB1C0L	TimerB1 counter Condition Register [7:0]										xxxx xxxx							
055h	TB1C1H	TimerB1 counter Condition Register [15:8]										xxxx xxxx							
056h	TB1C1L	TimerB1 counter Condition Register [7:0]										xxxx xxxx							
057h	TB1C2H	TimerB1 counter Condition Register [15:8]										xxxx xxxx							
058h	TB1C2L	TimerB1 counter Condition Register [7:0]										xxxx xxxx							
059h	TCCN0	-	TC1S[1:0]	-	-	-	-	-	-	0000 0000	uuuu uuuu	****							
061h	CFG	-	-	-	-	-	GCRST	ENI2CT	ENI2C	0000 0000	.... .uuu	-,-,-,-,-,-							
062h	ACT	SLAVE	ADR10	SLAVE24	I2CER	START	STOP	I2CINT	ACK	0000 0000	uuuu uuuu	****							
063h	STA	MACTF	SACTF	RDBF	RWF	DFF	ACKF	GCF	ARBF	0001 0000	uuuu uuuu	****							
064h	CRG	CRG[7:0]										0000 0000							
065h	TOC	I2CTF	DI2C[2:0]		I2CTL[3:0]					0000 0000	uuuu uuuu	****							
066h	RDB	RDB[7:1]										xxxx xxxx							
067h	TDB0	TDB0[7:1]										xxxx xxxx							
068h	SID0	SID0[7:1],The corresponding address of the 7-bit mode										SID0V[0]							
069h	UR0CN	ENSP	ENTX	TX9	TX9D	PARITY	-	-	-	0000 0..0	uuuu u..u	****,*,-,*							
06Ah	UR0STA	-	RC9D	PERR	FERR	OERR	RCIDL	TRMT	ABDOVF	.000 0010	.uuu uuuu	-,-,r,r,r,r,r,rw 0							
06Bh	BA0CN	-	-	-	-	ENCR	RC9	ENADD	ENABD	.... 0000	.... uuuu	-,-,-,-,-,-,-							
06Ch	BGORH	-	-	-	Baud Rate Generator Register High Byte					...x xxxx	...u uuuu	-,-,-,-,-,-,-							
06Dh	BG0RL	Baud Rate Generator Register Low Byte										xxxx xxxx							
06Eh	TX0R	UART Transmit Register										xxxx xxxx							
06Fh	RCREG	UART Receive Register										xxxx xxxx							
070h	PT1									PT1.0	xxxx xxxx	****							
074h	PT1M1	-	-	-	-	-				INTEGO[1:0]	0000 0000	uuuu uuuu							
075h	PT4	PT4.7	PT4.6	PT4.5	PT4.4	PT4.3					xxxx xxxx	****							
076h	TRISC4	TC4.7	TC4.6	TC4.5	TC4.4	TC4.3					0000 0000	uuuu uuuu							
077h	PT4DA	DA4.7	DA4.6	DA4.5	DA4.4	DA4.3					0000 0000	uuuu uuuu							
078h	PT4PU	PU4.7	PU4.6	PU4.5	PU4.4	PU4.3					0000 0000	uuuu uuuu							
079h	PT4PD1	PDR4.3[1:0]		-	-	-	-	-	-	0000 0000	uuuu uuuu	****							
07Ah	PT4PD2	PDR4.7[1:0]		PDR4.6[1:0]		PDR4.5[1:0]		PDR4.4[1:0]		0000 0000	uuuu uuuu	****							
07Bh	PT4INT	INTG4.7	INTG4.6							0000 0000	uuuu uuuu	****							
07Ch	PT4INTE	INTE4.7	INTE4.6							0000 0000	uuuu uuuu								
07Dh	PT4INTF	INTF4.7	INTF4.6							0000 0000	uuuu uuuu								
07Eh	PT4M2	-	PM4.7[0]	-	PM4.6[0]	-	-	-	-	0000 0000	uuuu uuuu								
080h ~ 0FFh		SRAM as 128Byte										uuuu uuuu							

Table 5-2 Data memory list (2)

## 6. Electrical Characteristics

Absolute maximum ratings over operating free-air temperature (unless otherwise noted)

Voltage applied at V <sub>DD</sub> to V <sub>SS</sub>	.....	-0.2 V to 6.0 V
Voltage applied to any pin	.....	-0.2 V to V <sub>DD</sub> + 0.3 V
Voltage applied to V <sub>PP</sub> pin	.....	-0.2 V to 8.75 V
Diode current at any device terminal	.....	±2 mA
Operating temperature range	.....	-40°C to 85°C
Storage temperature, T <sub>stg</sub> : (unprogrammed device)	.....	-55°C to 150°C
(programmed device)	.....	-40°C to 85°C
Total power dissipation.	.....	0.5w
Maximum output current sink by any port I/O pin.	.....	.25mA

### 6.1. Recommended Operating Conditions

T<sub>A</sub> = -40°C ~ 85°C, unless otherwise noted

Sym.	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V <sub>DD</sub>	Digital Supply Voltage	All digital peripherals and CPU	2.2	5.5	5.5	V
V <sub>DDA</sub>	Analog Supply Voltage	Analog peripherals	2.4	4.5	4.5	V
V <sub>SS</sub>	Supply Voltage		0	0	0	

### 6.2. Internal RC Oscillator

T<sub>A</sub> = 25°C, V<sub>DD</sub> = 3.0V, unless otherwise noted

Sym.	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
HAO(2MHz)	High Speed Oscillator frequency	ENHAO[0]=1, HAOM[1:0]=00	-20%	2.0	+20%	MHz
HAO(4MHz)	High Speed Oscillator frequency	ENHAO[0]=1, HAOM[1:0]=01	-20%	4.0	+20%	MHz
HAO(8MHz)	High Speed Oscillator frequency	ENHAO[0]=1, HAOM[1:0]=11	-20%	8.0	+20%	MHz
LPO	Low Power Oscillator frequency	V <sub>DD</sub> supply voltage be enable LPO	-20%	14.5	+20%	KHz

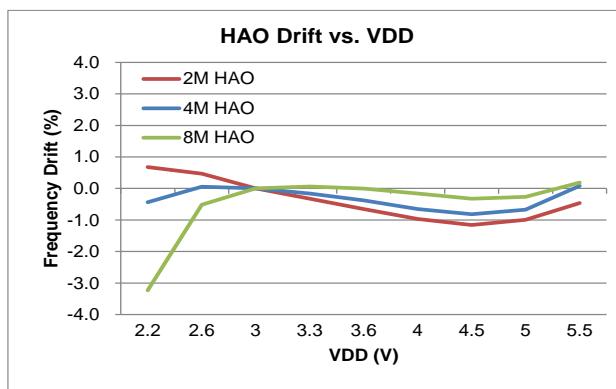


Figure 6.2-1 HAO vs. VDD

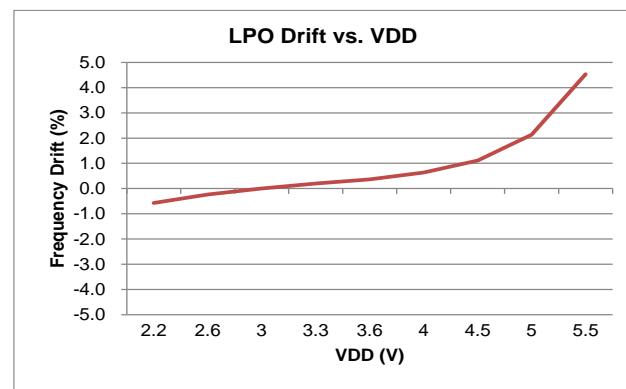


Figure 6.2-2 LPO vs. VDD

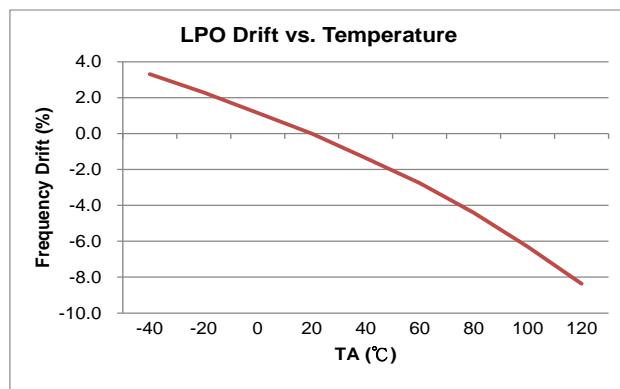


Figure 6.2-3 LPO vs. Temperature

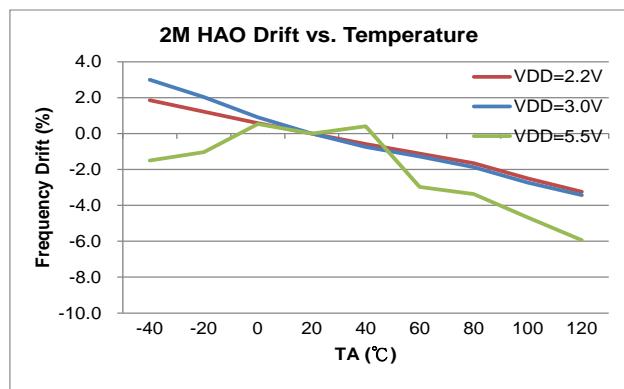


Figure 6.2-4 HAO (2.0MHz) vs. Temperature

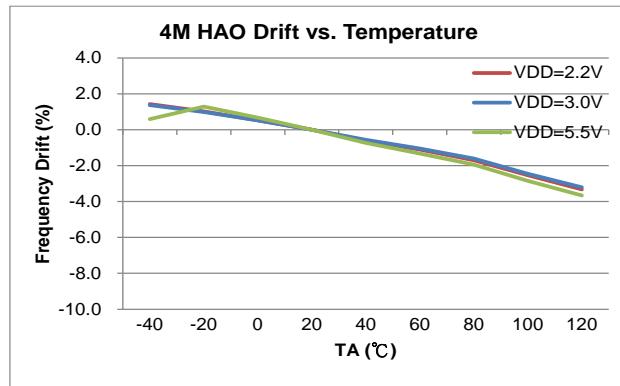


Figure 6.2-5 HAO (4.0MHz) vs. Temperature

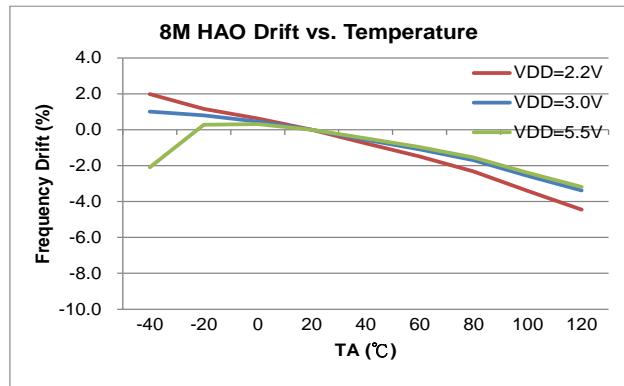


Figure 6.2-6 HAO (8.0MHz) vs. Temperature

### 6.3. Supply current into VDD excluding peripherals current

$T_A = 25^\circ C, V_{DD} = 3.0V, OSC\_LPO = 14.5KHz$ , unless otherwise noted

Sym.	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$I_{AM1}$	Active mode 1	OSC_CY = off, OSC_HAO = 8MHz, CPU_CK = 8MHz		600	1000	uA
$I_{AM2}$	Active mode 2	OSC_CY = off, OSC_HAO = 4MHz, CPU_CK = 4MHz		320	650	uA
$I_{AM3}$	Active mode 3	OSC_CY = off, OSC_HAO = 2MHz, CPU_CK = 2MHz		210	450	uA
$I_{AM4}$	Active mode 4	OSC_CY = off, OSC_HAO = 2MHz, CPU_CK = 1MHz		160	350	uA
$I_{LP1}$	Low Power 1	OSC_CY = off, OSC_HAO = off, CPU_CK = LPO,		2	5	uA
$I_{LP2}$	Low Power 2	OSC_CY = off, OSC_HAO = off, CPU_CK = LPO, Idle state		1.0	2.5	uA
$I_{LP3}$	Low Power 3	OSC_CY = off, OSC_HAO = off, CPU_CK = off, Sleep state		0.25	1.0	uA

$T_A = 25^\circ C, V_{DD} = 5.5V, OSC\_LPO = 14.5KHz$ , unless otherwise noted

Sym.	Parameter	Test Conditions	Min.	Typ.	Max.	unit
$I_{AM1}$	Active mode 1	OSC_CY = off, OSC_HAO = 8MHz, CPU_CK = 8MHz		1200	1800	uA
$I_{AM2}$	Active mode 2	OSC_CY = off, OSC_HAO = 4MHz, CPU_CK = 4MHz		720	1200	uA
$I_{AM3}$	Active mode 3	OSC_CY = off, OSC_HAO = 2MHz, CPU_CK = 2MHz		500	1000	uA
$I_{AM4}$	Active mode 4	OSC_CY = off, OSC_HAO = 2MHz, CPU_CK = 1MHz		400	800	uA
$I_{LP1}$	Low Power 1	OSC_CY = off, OSC_HAO = off, CPU_CK = LPO,		4	10	uA
$I_{LP2}$	Low Power 2	OSC_CY = off, OSC_HAO = off, CPU_CK = LPO, Idle state		2.5	5	uA
$I_{LP3}$	Low Power 3	OSC_CY = off, OSC_HAO = off, CPU_CK = off, Sleep state		0.4	2	uA

OSC\_HAO : Internal High Accuracy Oscillator frequency.

CPU\_CK : CPU core work frequency.

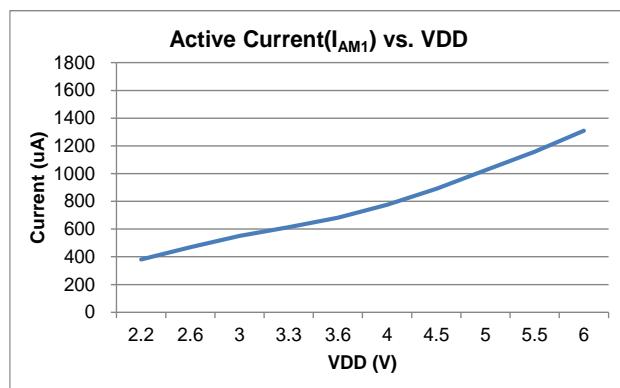


Figure 6.3-1  $I_{AM1}$  vs. VDD

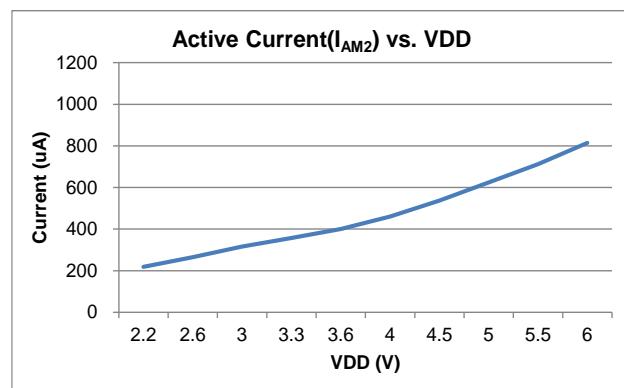
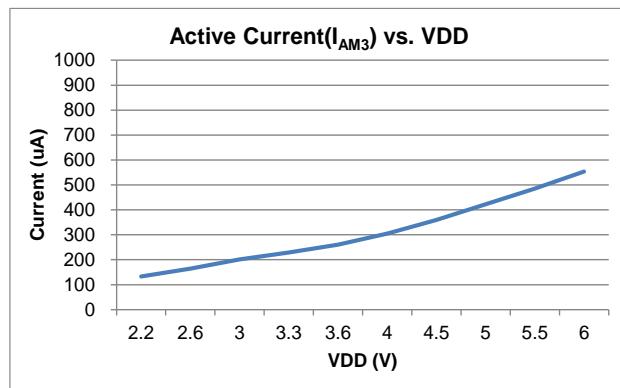
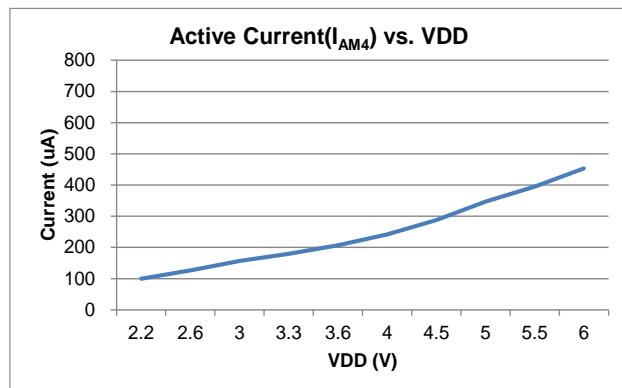
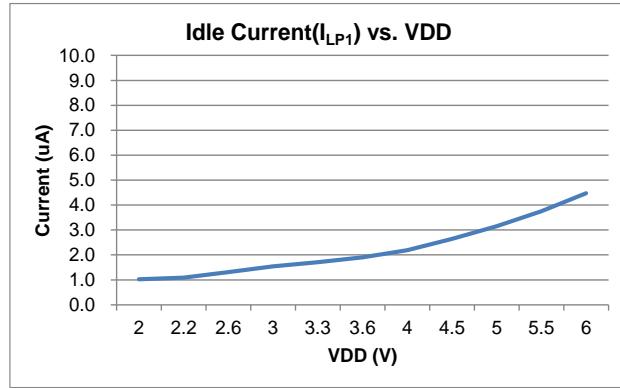
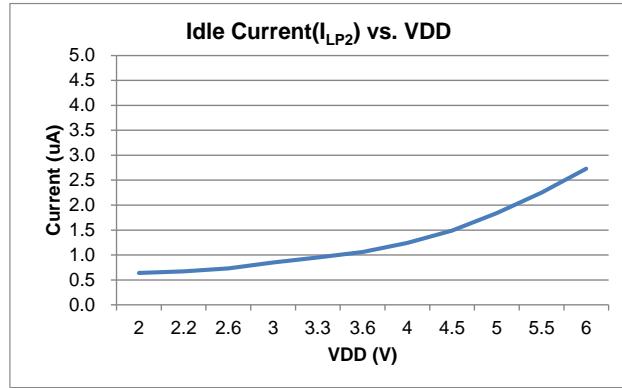
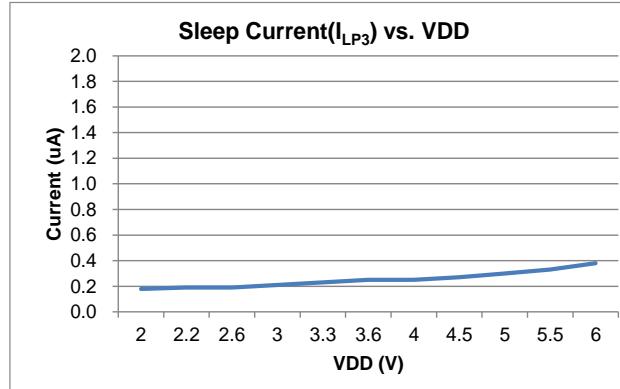
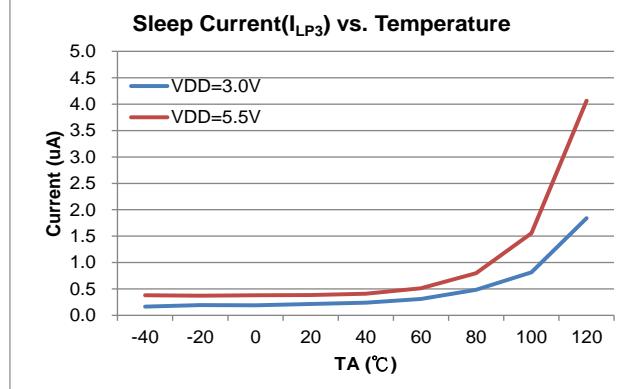


Figure 6.3-2  $I_{AM2}$  vs. VDD

Figure 6.3-3  $I_{AM3}$  vs. VDDFigure 6.3-4  $I_{AM4}$  vs. VDDFigure 6.3-5  $I_{LP1}$  vs. VDDFigure 6.3-6  $I_{LP2}$  vs. VDDFigure 6.3-7  $I_{LP3}$  vs. VDDFigure 6.3-8  $I_{LP3}$  vs. Temperature

## 6.4. Port4

$T_A = 25^\circ\text{C}$ ,  $V_{DD} = 3.0\text{V}$ , unless otherwise noted

Sym.	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
<b>Input voltage and Schmitt trigger and leakage current and timing</b>						
$V_{IH}$	High-Level input voltage		$0.7 \cdot V_{DD}$	$V_{DD}$		V
$V_{IL}$	Low-Level input voltage		$V_{SS}$	$0.3 \cdot V_{DD}$		
$V_{hys}$	Input Voltage hysteresis( $V_{IH} - V_{IL}$ )			0.8		V
$I_{LKG}$	Leakage Current				0.1	uA
$R_{PU}$	Port pull high resistance				60	k $\Omega$
$R_{PD}$	Port pull low resistance	PDR4.x/APDRX0 [1:0]=01			10	k $\Omega$
		PDR4.x/APDRX0 [1:0]=10			50	k $\Omega$
		PDR4.x/APDRX0 [1:0]=11			100	k $\Omega$
<b>Output voltage and current</b>						
$V_{OH}$	High-level output voltage	$V_{DD} < 4\text{V}$ , $I_{OH}=10\text{mA}$	$V_{DD} - 0.4$			V
		$V_{DD} \geq 4\text{V}$ , $I_{OH}=15\text{mA}$	$V_{DD} - 0.4$			
$V_{OL}$	Low-level output voltage	$V_{DD} < 4\text{V}$ , $I_{OL}=-10\text{mA}$		$V_{SS} + 0.3$		
		$V_{DD} \geq 4\text{V}$ , $I_{OL}=-15\text{mA}$		$V_{SS} + 0.3$		

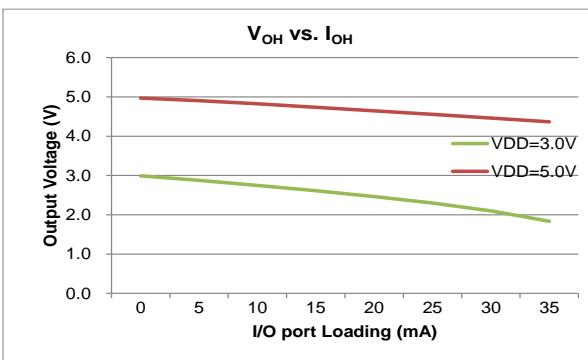


Figure 6.4-1  $V_{OH}$  vs.  $I_{OH}$

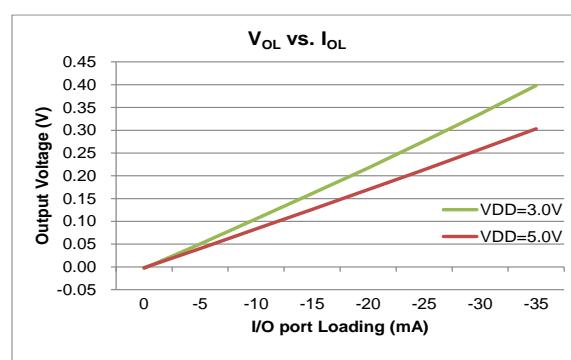


Figure 6.4-2  $V_{OL}$  vs.  $I_{OL}$

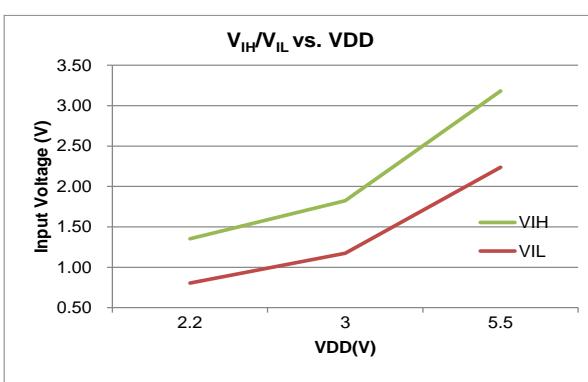


Figure 6.4-3  $V_{IH}/V_{IL}$  vs.  $VDD$

## 6.5. Rest(Brownout)

$T_A = 25^\circ\text{C}$ ,  $V_{DD} = 3.0\text{V}$ , unless otherwise noted

Sym.	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
BOR	Pulse length needed to accepted reset internally, $t_{d-LVR}$		2			uS
	$V_{DD}$ Start Voltage to accepted reset internally ( $L \rightarrow H$ ), $V_{HYS}$		1.6	1.74	2.1	V
	$V_{DD}$ Start Voltage to accepted reset internally ( $H \rightarrow L$ ), $V_{LVR}$		1.6	1.70	2.1	V
	Hysteresis, $V_{HYS-LVR}$			40		mV
BOR : Brownout Reset						

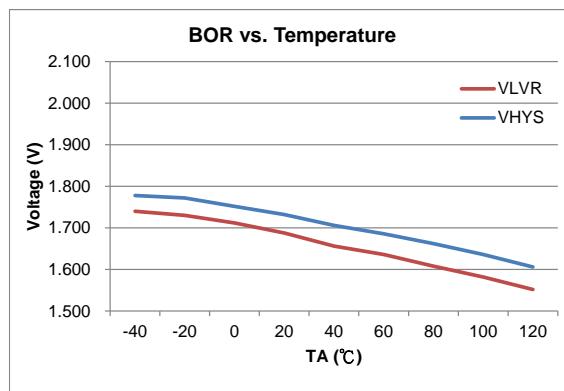


Figure 6.5-1 BOR vs. Temperature

## 6.6. Power System

$T_A = 25^\circ C, V_{DD} = 3.0V$ , unless otherwise noted

Sym.	Parameter	Test Conditions		Min.	Typ.	Max.	Unit
VDDA	VDDA operation current, $I_{VDDA}$	$I_L = 0mA$	$LDOC[2:0]=000b$		20		uA
	Select VDDA output voltage	$I_L = 0.1mA, VDD \geq VDDA + 0.25V$	$LDOC[2:0]=000b$		2.4		V
			$LDOC[2:0]=001b$		2.6		
			$LDOC[2:0]=010b$		2.9		
			$LDOC[2:0]=011b$		3.3		
			$LDOC[2:0]=100b$		3.6		
			$LDOC[2:0]=101b$		4.0		
	Dropout voltage	$I_L = 10mA$	$LDOC[2:0]=000b$		250		mV
ACM	Temperature drift	$LDOC[2:0]=000b, I_L = 0.1mA$	$T_A = -40^\circ C \sim 85^\circ C$		50		ppm/ $^\circ C$
	$V_{DD}$ Voltage drift		$V_{DD}=2.5V \sim 5.5V$		$\pm 0.2$		%/V
V12	ACM operation current, $I_{ACM}$	$ENADC[0]=1b$	$ENACM[0]=1b$		50		uA
	Internal Analog Common Mode Voltage, $V_{ACM}=VDDA/2$		$I_L = 0uA$		$VDDA/2$		V
	Temperature drift	$ENADC[0]=1b$	$T_A = -40^\circ C \sim 85^\circ C, ENACM[0]=1b$		50		ppm/ $^\circ C$
V12	V12 operation current, $I_{V12}$	$ENADC[0]=1b$	$ENV12[0]=1b$		50		uA
	Internal Analog Common Mode Voltage, $V_{12}$		$I_L = 0uA$		1.2		V
	Temperature drift	$ENADC[0]=1b$	$T_A = -40^\circ C \sim 85^\circ C, ENV12[0]=1b$		50		ppm/ $^\circ C$
<p>VDDA : Adjust Voltage Regulator</p> <p>V12 : Internal Analog Common Mode Voltage (No output voltage)</p> <p>ACM : Internal Analog Common Mode Voltage <math>VDDA/2</math> (No voltage output)</p>							

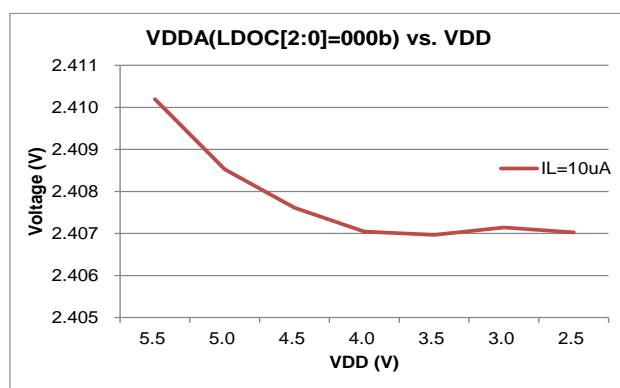


Figure 6.6-1 VDDA(000b) vs. VDD

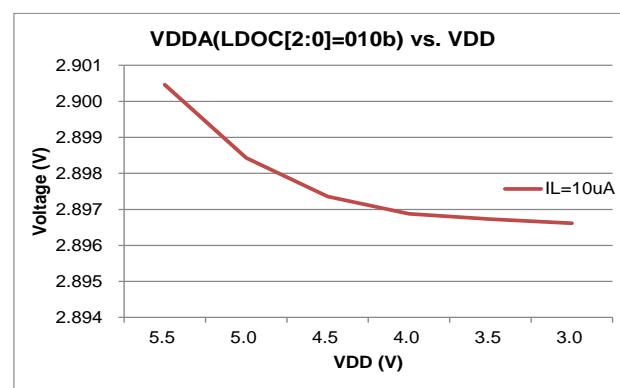


Figure 6.6-2 VDDA(010b) vs. VDD

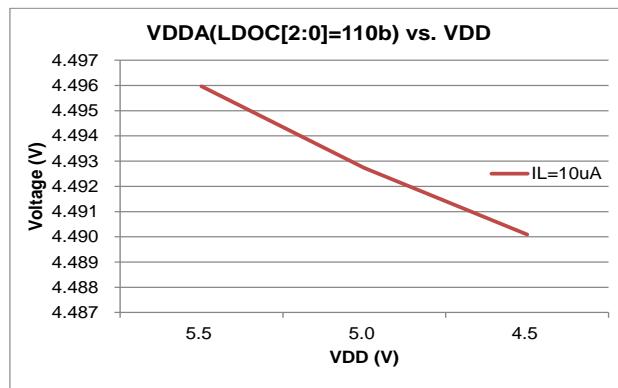


Figure 6.6-3 VDDA(110b) vs. VDD

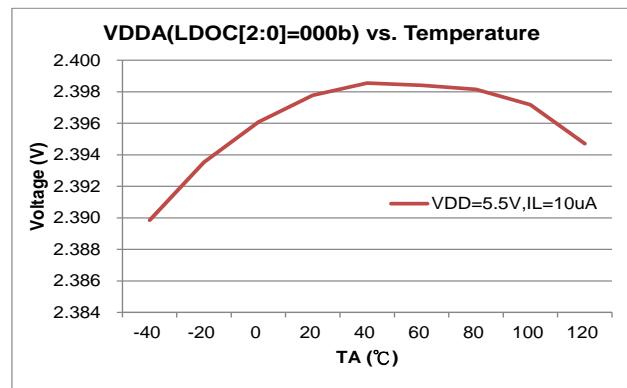


Figure 6.6-4 VDDA(000b) vs. Temperature

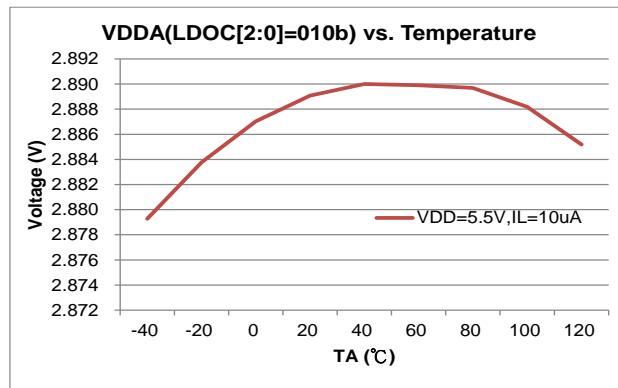


Figure 6.6-5 VDDA(010b) vs. Temperature

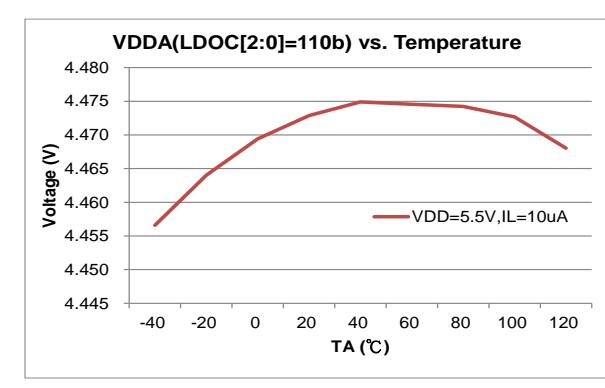


Figure 6.6-6 VDDA(110b) vs. Temperature

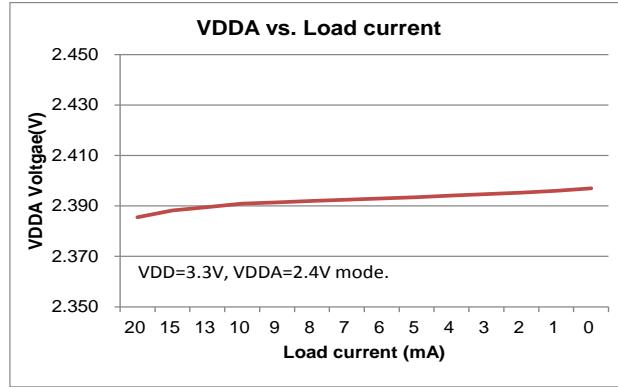


Figure 6.6-7 VDDA vs. Load current

## 6.7. $\Sigma\Delta$ ADC, Power Supply and recommended operating conditions

$T_A = 25^\circ C$ ,  $V_{DD} = 3.0V$ ,  $VDDA=2.4V$ ,unless otherwise noted

Sym.	Parameter	Test Conditions		Min.	Typ.	Max.	Unit		
$V_{SD18}$	Supply Voltage at VDDA	$ENVDDA[0]=0$		2.4	4.5		V		
$f_{SD18}$	Modulator sample frequency, ADC_CK			125	500		KHz		
	Over Sample Ratio, OSR			64	32768				
$I_{SD18}$	Operation supply current without PGA	$ENADC[0]=1$	GAIN =1, ADC_CK=500KHz	260			uA		

### 6.7.1. $\Sigma\Delta$ ADC, performance

$T_A = 25^\circ C$ ,  $V_{DD} = 3.0V$ ,  $VDDA=2.4V$ ,  $V_{VR}=1.0V$ , GAIN=1,  $f_{SD18}=500KHz$  ,unless otherwise noted

Sym.	Parameter	Test Conditions		Min.	Typ.	Max.	unit			
INL	Integral Nonlinearity(INL)	$VDDA=2.4V$ , $V_{VR}=1.0V$ , $\Delta SI=\pm 450mV$		$\pm 0.01$			%FSR			
	No Missing Codes <sup>3</sup>	$ADC\_CK=500Khz$ , $OSR[3:0]=0001b$		23			Bits			
$G_{SD18}$	Temperature drift <b>Gain 1~x16</b>			$T_A= -40^\circ C \sim 85^\circ C$	10		ppm/ $^\circ C$			
Eos	Offset error of Full Scale Rang input voltage range with Chopper	$\Delta AI=0V$ $\Delta VR=0.9V$ $DCSET[2:0]=<000>$ * $\Delta AI$ is external short	Gain=2	1			%FSR			
	Gain=1		2				uV/ $^\circ C$			
	Gain=2		1							
	Gain=4		0.5							
	Gain=16		0.15							
			90				dB			
CM <sub>SD18</sub>	Common-mode rejection	$V_{CM}=0.7V$ to $1.7V$ , $V_{VR}=1.0V$	$V_{SI}=0V$ , GAIN=1	75						
		$V_{CM}=0.7V$ to $1.7V$ , $V_{VR}=1.0V$ ,	$V_{SI}=0V$ , GAIN=16							
PSRR	DC power supply rejection	$VDDA=3.0V$ , $\Delta VDDA=\pm 100mV$ , $V_{VR}=1.0V$ , $V_{SI}=V_{SL}=1.2V$ ,	Gain=1	75			dB			
			Gain=16							

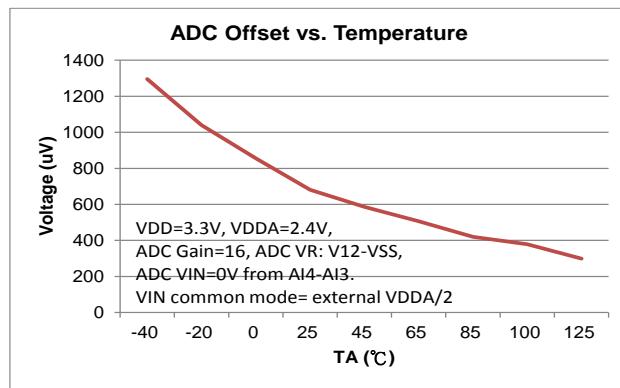


Figure 6.7-1 ADC Offset drift with Temperature

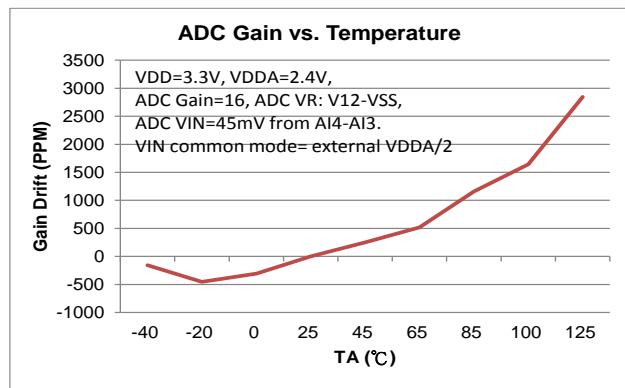


Figure 6.7-2 ADC Gain drift with Temperature

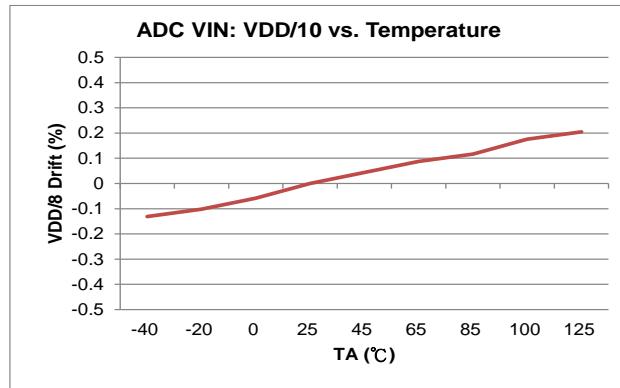


Figure 6.7-3 VDD/10 drift with Temperature

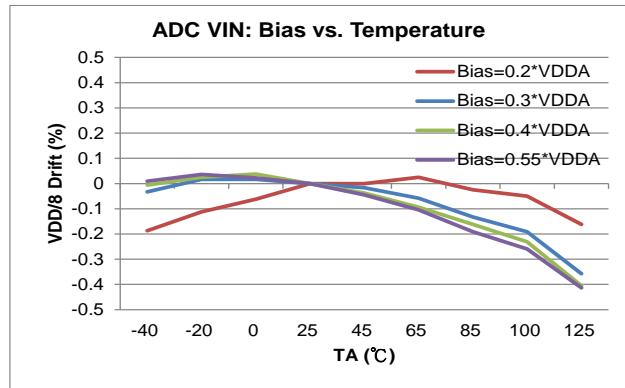


Figure 6.7-4 Bias drift with Temperature

### 6.7.2. ΣΔADC Noise Performance

Provide important input noise specifications for the ΣΔ ADC. Table 6.7-2 (a), Table 6.7-2 (b) lists typical noise specifications such as gain, output rate and single-ended maximum input voltage, etc. The test conditions are set on the AI3-AI4 external input short, and the ADC reference voltage source is using the internal V12 and VSS, when the reference voltage network, the equivalent reference voltage is 1.2V, sampling 1024 data.

$T_A = 25^\circ C$ ,  $V_{DD} = 3.3V$ ,  $VDDA=2.4V$ , unless otherwise noted

<i>ENOB(RMS) with OSR/GAIN at A/D Clock=500Khz, VDDA=2.4V, VREF=1.2V</i>													
Max. Vin(mV) $=0.9 \times VREF^{(1)}$	OSR			64	128	256	512	1024	2048	4096	8192	16384	32768
	Output rate(HZ)			7813	3906	1953	977	488	244	122	61	31	15
	Gain	=	ADGN										
$\pm 2160$	0.25	=	0.25	13.6	15.8	16.2	16.6	17.1	17.6	17.9	18.4	18.7	18.2
$\pm 2160$	0.5	=	0.5	13.4	15.7	16.3	16.7	17.1	17.6	18.0	18.5	18.6	18.2
$\pm 1080$	1	=	1	13.7	15.7	16.2	16.7	17.2	17.5	17.9	18.3	18.7	18.5
$\pm 540$	2	=	2	12.4	15.6	16.1	16.6	17.1	17.6	18.0	18.0	18.0	18.8
$\pm 270$	4	=	4	12.6	15.5	16.0	16.5	17.0	17.5	17.6	17.7	18.3	18.7
$\pm 135$	8	=	8	13.5	15.3	15.8	16.3	16.7	17.1	17.4	18.0	18.4	18.4
$\pm 68$	16	=	16	11.7	15.0	15.5	16.0	16.4	16.8	17.2	17.9	18.4	18.7

(1) Max.Vin (mV) is the max. input voltage of single end to ground (VSS).

Table 6.7-2(a) ADC ENOB Table

<i>RMS Noise(uV) with OSR/GAIN at A/D Clock=500Khz, VDDA=2.4V, VREF=1.2V</i>													
Max. Vin(mV) $=0.9 \times VREF^{(1)}$	OSR			64	128	256	512	1024	2048	4096	8192	16384	32768
	Output rate(HZ)			7813	3906	1953	977	488	244	122	61	31	15
	Gain	=	ADGN										
$\pm 2160$	0.25	=	0.25	764.77	173.20	130.68	95.36	69.10	47.20	40.37	28.33	22.78	32.07
$\pm 2160$	0.5	=	0.5	443.87	92.50	61.54	44.77	34.33	24.33	17.85	13.45	12.48	15.83
$\pm 1080$	1	=	1	181.43	45.93	31.25	23.10	16.54	12.83	9.56	7.24	5.62	6.47
$\pm 540$	2	=	2	227.93	24.03	16.91	12.11	8.72	6.19	4.66	4.56	4.53	2.65
$\pm 270$	4	=	4	99.24	13.10	9.27	6.65	4.73	3.35	2.93	2.85	1.86	1.43
$\pm 135$	8	=	8	25.56	7.30	5.43	3.82	2.80	2.11	1.70	1.14	0.87	0.86
$\pm 68$	16	=	16	44.04	4.52	3.15	2.33	1.76	1.32	1.03	0.64	0.44	0.36

Table 6.7-2(b) ADC RMS Noise Table

Also for high voltage conditions with  $VDD = VDDA = 5V$ , the ΣΔ ADC provides important input noise specifications. Table 6.7-2 (c), Table 6.7-2 (d) lists the typical noise specifications such as gain, output rate, and single-ended maximum input voltage, etc. Test conditions set in AI3-AI4 external input signal short, ADC reference voltage source for the use of internal  $VDDA / 2$  and VSS. when the reference voltage source network, the equivalent reference voltage of 2.5V, sampling 1024 data.

# HY15P41

## Embedded 24-Bit ΣΔADC

8-Bit RISC-like Mixed Signal Microcontroller



ENOB(RMS) with OSR/GAIN at VDD=VDDA=5.0V, A/D Clock=500Khz, VR=VDDA/2-VSS											
Max. Vin(mV) =0.9*VREF (1)	OSR	64	128	256	512	1024	2048	4096	8192	16384	32768
	Output rate(HZ)	7813	3906	1953	977	488	244	122	61	31	15
	GAIN										
±9000	1/4	14.4	15.6	16.1	16.7	17.0	17.6	18.0	18.6	19.1	19.5
±4500	1/2	14.1	15.8	16.3	16.9	17.4	17.8	18.2	18.7	19.3	19.7
±2250	1	13.8	15.7	16.2	16.7	17.1	17.7	18.1	18.5	19.0	19.5
±1125	2	14.4	15.6	16.4	16.8	17.3	17.9	18.2	18.7	19.2	19.6
±562.5	4	13.0	15.6	16.3	16.7	17.1	17.7	18.1	18.6	19.1	19.5
±281.25	8	14.5	15.5	16.1	16.6	17.1	17.5	17.9	18.4	18.8	19.3
±140.625	16	11.7	15.5	16.1	16.6	17.0	17.3	17.6	18.4	18.8	19.3

Table 6.7-2(c) ADC ENOB Table

RMS Noise(uV) with OSR/GAIN at VDD=VDDA=5.0V, A/D Clock=500Khz, VR=VDDA/2-VSS											
Max. Vin(mV) =0.9*VREF (1)	OSR	64	128	256	512	1024	2048	4096	8192	16384	32768
	Output rate(HZ)	7813	3906	1953	977	488	244	122	61	31	15
	GAIN										
±9000	1/4	960.2	407.4	278.9	192.6	148.2	99.9	76.4	51.9	36.4	27.5
±4500	1/2	590.3	178.7	124.1	80.1	58.8	44.4	34.2	24.3	15.7	12.1
±2250	1	344.9	93.0	64.5	48.0	35.0	24.1	17.5	13.8	9.8	6.8
±1125	2	118.9	49.2	29.8	22.5	15.8	10.2	8.5	5.7	4.1	3.2
±562.5	4	155.7	25.5	15.8	11.8	8.9	5.8	4.5	3.1	2.3	1.6
±281.25	8	26.8	13.2	8.8	6.5	4.4	3.3	2.5	1.8	1.3	1.0
±140.625	16	97.0	6.7	4.6	3.3	2.5	1.9	1.5	0.9	0.7	0.5

Table 6.7-2(d) ADC RMS Noise Table

The RMS noise is referred to the input. The Effective Number of Bits (ENOB (RMS Bit)) is defined as:

$$\text{ENOB(RMS)} = \frac{\ln\left(\frac{\text{FSR}}{\text{RMS Noise}}\right)}{\ln(2)}$$

$$\text{RMS Noise} = \sqrt{2 \times \text{VREF} \times \sum_{k=1}^{1024} (\text{ADO}[k] - \text{Average})^2} / 2^{23}$$

Where FSR (Full - Scale Range) =  $2 \times \text{VREF}/\text{Gain}$ .

$$\text{Average} = \frac{\sum_{k=1}^{1024} (\text{ADO}[k])}{1024}$$

# HY15P41

Embedded 24-Bit  $\Sigma\Delta$ ADC

8-Bit RISC-like Mixed Signal Microcontroller

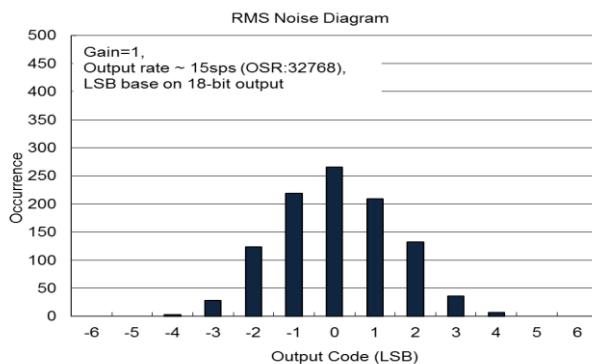


Figure 6.7-5 RMS Noise Diagram

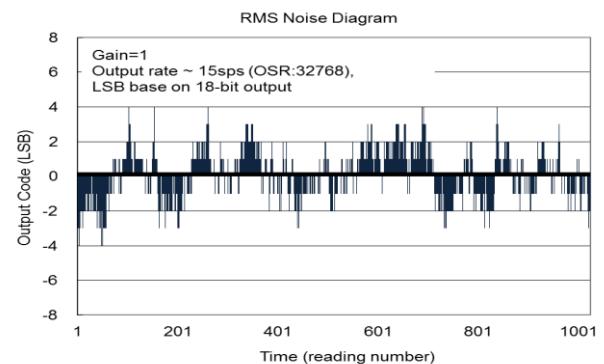


Figure 6.7-6 Output Code Diagram

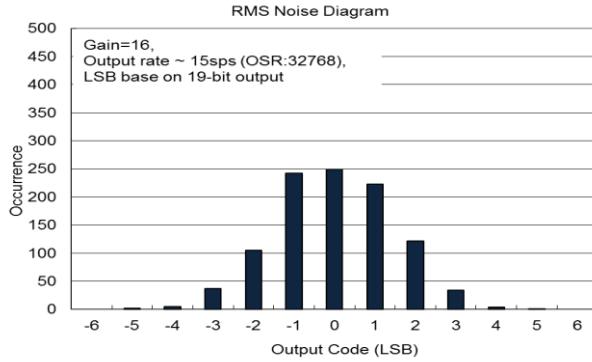


Figure 6.7-7 RMS Noise Diagram

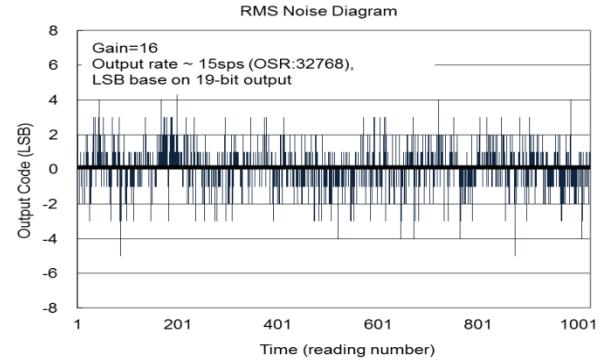


Figure 6.7-8 Output Code Diagram

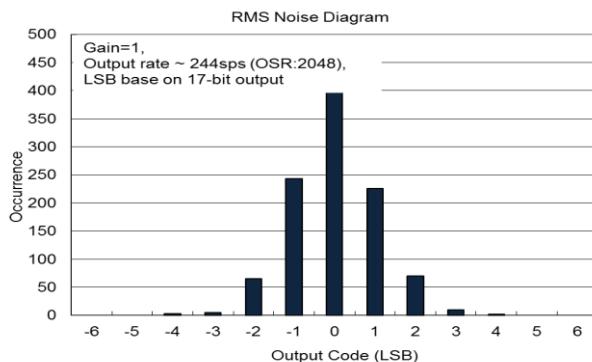


Figure 6.7-9 RMS Noise Diagram

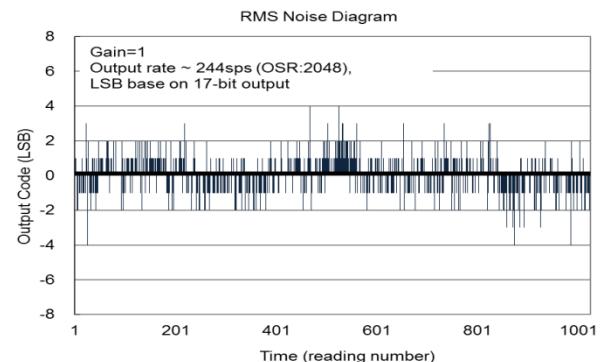


Figure 6.7-10 Output Code Diagram

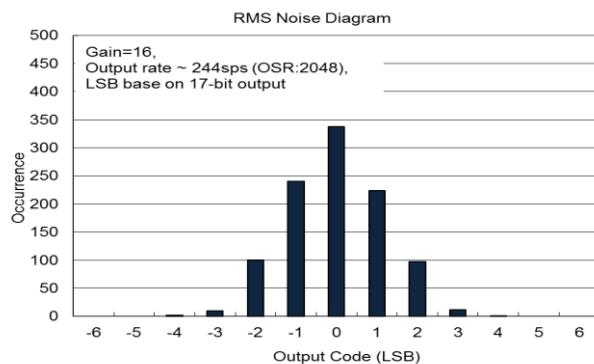


Figure 6.7-11 RMS Noise Diagram

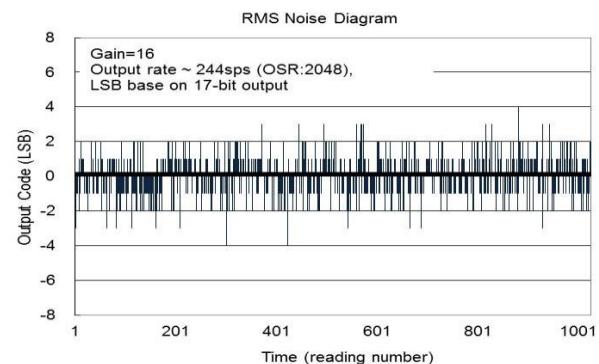


Figure 6.7-12 Output Code Diagram

### 6.7.3. $\Sigma\Delta$ ADC, Temperature Sensor

$T_A = 25^\circ\text{C}$ ,  $V_{DD} = 3.0\text{V}$ ,  $VDDA=2.4\text{V}$ , unless otherwise noted

Sym.	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$TC_S$	Sensor temperature drift			173		$\mu\text{V}/^\circ\text{C}$
$KT$	Absolute Temperature Scale $0^\circ\text{K}$			-284		$^\circ\text{C}$
$TC_{ERR}$	One point calibrate error temperature	Calibration at $25^\circ\text{C}$ of $-40^\circ\text{C} \sim 85^\circ\text{C}$		$\pm 2$		$^\circ\text{C}$

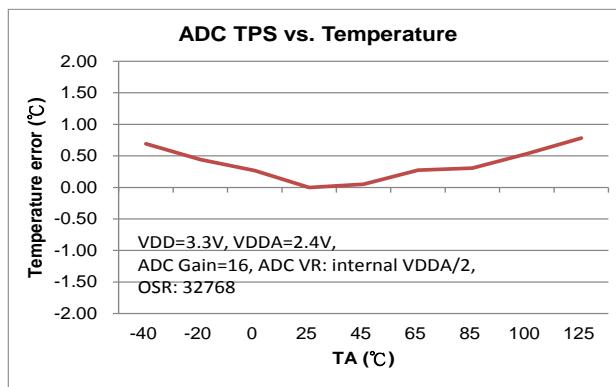


Figure 6.7-13 ADC Temperature Error

## 6.8. Build-In EPROM(BIE)

$T_A = 25^\circ C$ ,  $V_{DD} = 3.0V$ , unless otherwise noted

Sym.	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$T_O$	Operation temperature range		0	25	40	°C
$V_{DD}$	Operation supply Voltage		2.75		5.5	V
$V_{BIE}$	Supply Voltage			8.5	8.75	V
$I_{BIE}$	Operation supply current			5		mA
$V_{SS}$	Supply Voltage			0		V

When connecting to the external  $V_{BIE}$  power source to program the BIE block, users can use the instruction to program the words one by one into the BIE block.

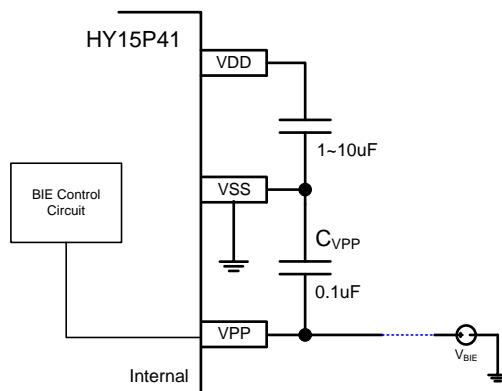


Figure 6-8 BIE typical application block diagram

## 7. Ordering Information

Device No. <sup>1</sup>	Package Type	Pins	Package Drawing		Code <sup>2</sup>	Shipment Packing Type	Unit Q'ty	Material Composition	MSL <sup>3</sup>
HY15P41-AS12	DFN	12	A	S12	000	Tape & Reel	5000	Green <sup>4</sup>	MSL-3
HY15P41-S016	SOP	16	S	016	000	Tube	50	Green <sup>4</sup>	MSL-3
HY15P41-S016	SOP	16	S	016	000	Tape & Reel	2500	Green <sup>4</sup>	MSL-3
HY15P41-S008	SOP	8	S	008	000	Tube	100	Green <sup>4</sup>	MSL-3
HY15P41-S008	SOP	8	S	008	000	Tape & Reel	2500	Green <sup>4</sup>	MSL-3

**<sup>1</sup>Device No.: Model No. – Package Type Description – Code** (Blank Code/ Standard/ Customized Programming Code)

Ex: Your customized programming code is 007 and you require SOP16 shipment.

The device No. will be HY15P41-S016-007.

Ex: You request blank code in SOP16 package.

The device No. will be HY15P41-S016.

Ex: Your customized programming code is 008 and you require products in SOP8 pack age. The device No. will be HY15P41-S008-008 and need to Tape & Reel shipping, then in Addition to the next single device No, please specify the form of shipping packaging Tape & Reel

**<sup>2</sup>Code:**

“001”~“999” is standard or customized programming code. Blank code does not have these numbers.

**<sup>3</sup>MSL:**

The Moisture Sensitivity Level ranking conforms to IPC/JEDEC J-STD-020 industry standard categorization. The products are processed, packed, transported and used with reference to IPC/JEDEC J-STD-033.

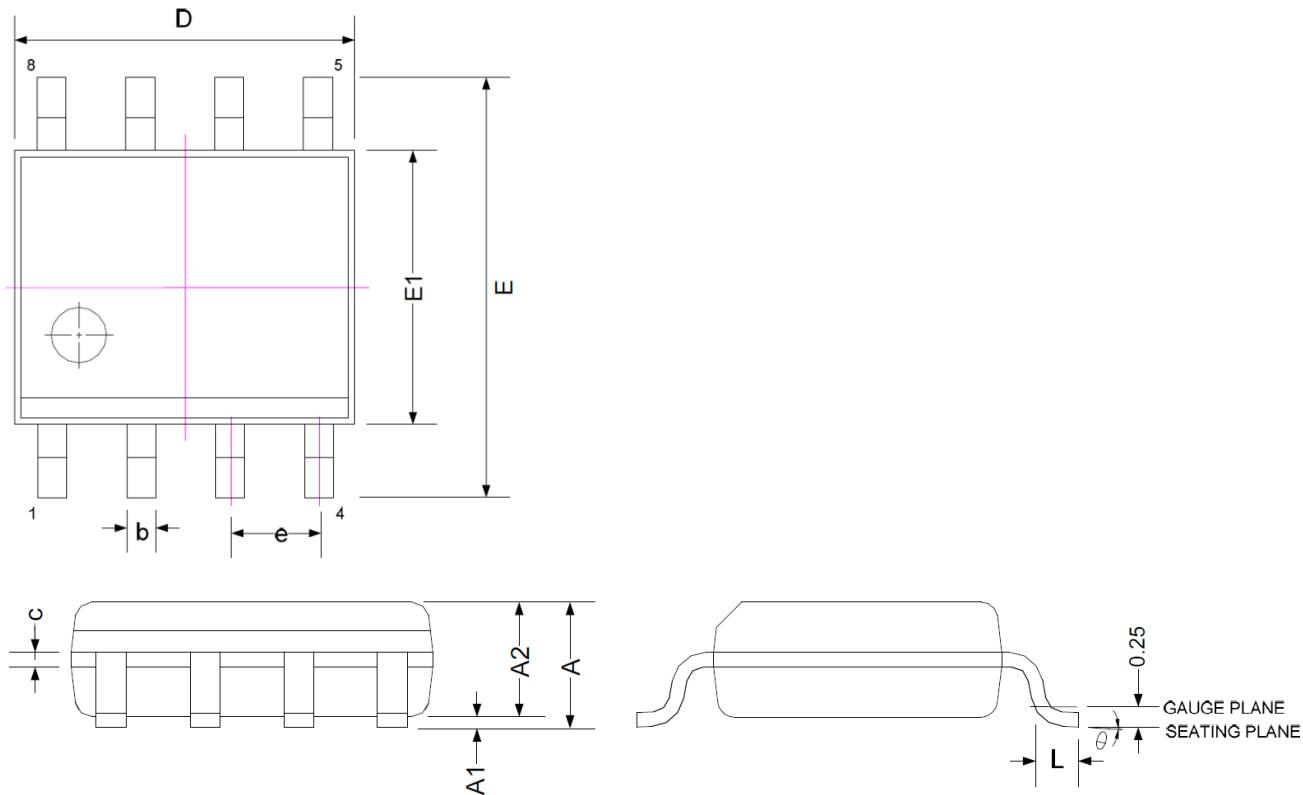
**<sup>4</sup> Green (RoHS & no Cl/Br):**

HYCON products are Green products that are compliant with RoHS directive, RoHS-compliant and halogen-free requirements (Br<900ppm or Cl<900ppm or (Br+Cl) <1500ppm)

## 8. Package Information

### 8.1. SOP8(S008)

#### 8.1.1. Package Dimensions SOP8(150mil)



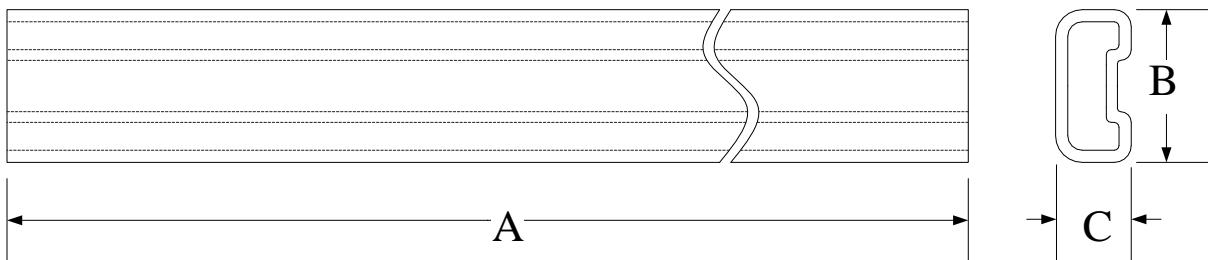
SYMBOLS	MIN	NOM	MAX
A	-	-	1.75
A1	0.10	-	0.25
A2	1.25	-	-
b	0.31	-	0.51
c	0.10	-	0.25
D	4.90 BSC		
E1	3.90 BSC		
E	6.00 BSC		
L	0.40	-	1.27
e	1.27 BSC		
$\theta$ °	0	-	8

Note:

1. All dimensions refer to JEDEC OUTLINE MS-012.
2. Do not include Mold Flash or Protrusions.
3. Unit: mm.

**8.1.2. Tube Dimensions SOP8(S008)**

Unit : mm



Type 1:

SYMBOLS	A	B	C
Spec.	521.0±1.0	7.747±0.15	3.810±0.15

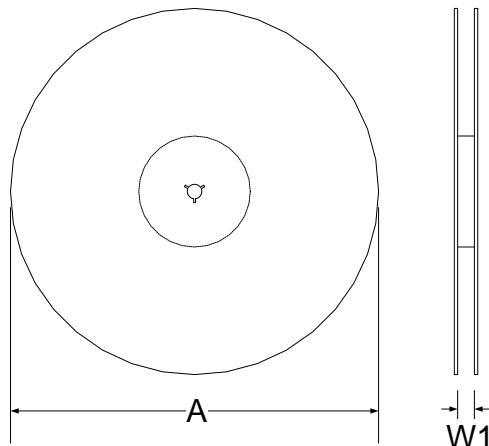
Type 2:

SYMBOLS	A	B	C
Spec.	521.0±1.0	7.874 REF.	3.810 REF.

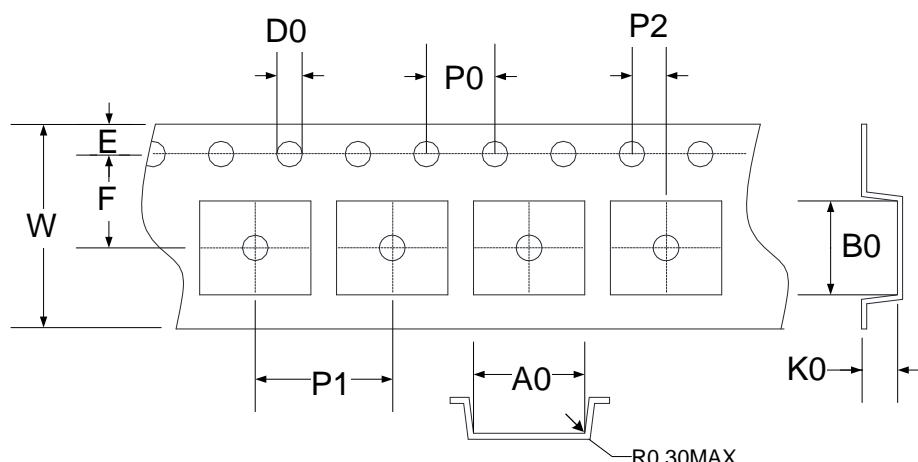
### 8.1.3. Tape & Reel Information

#### 8.1.3.1. Reel Dimensions –Type1

Unit : mm



#### 8.1.3.2. Carrier Tape Dimensions

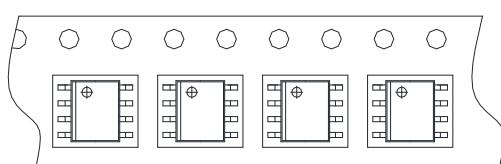


SYMBOLS	Reel Dimensions		Carrier Tape Dimensions										
	A	W1	A0	B0	K0	P0	P1	P2	E	F	D0	W	
Spec.	330	12.5	6.90	5.40	2.00	4.00	8.00	2.00	1.75	5.50	1.50	12.00	
Tolerance	+6/-3	+1.5/-0	$\pm 0.10$	$\pm 0.10$	$\pm 0.10$	$\pm 0.10$	$\pm 0.10$	$\pm 0.05$	$\pm 0.10$	$\pm 0.05$	$\pm 0.10$	$\pm 0.1/-0$	$\pm 0.30$

Note: 10 Sprocket hole pitch cumulative tolerance is  $\pm 0.20$ mm.

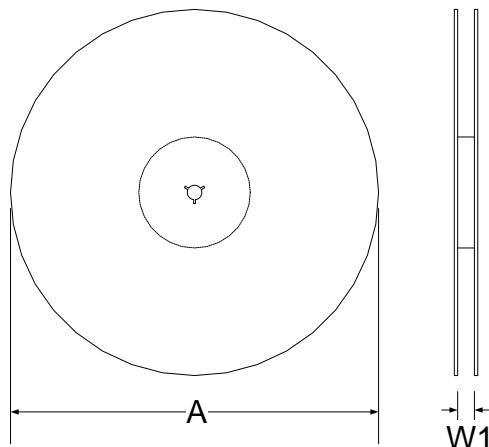
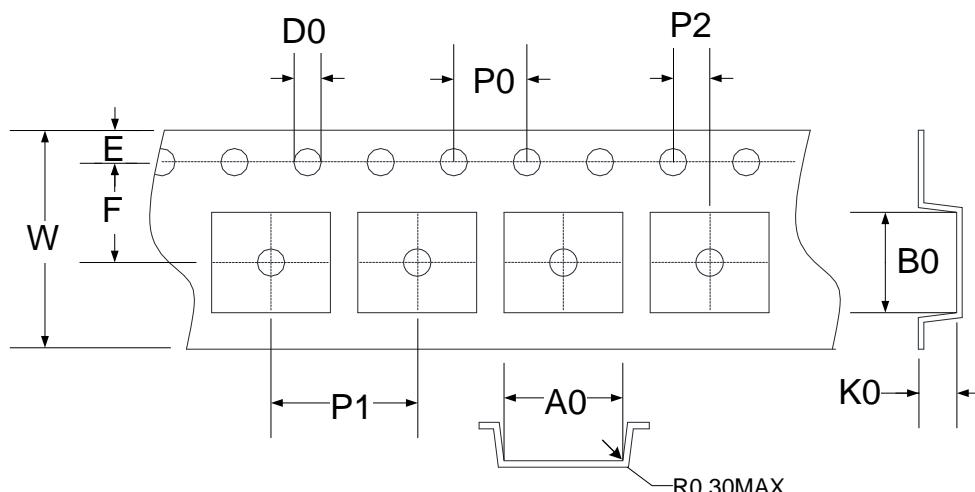
Unit : mm

#### 8.1.3.3. Pin1 direction



**8.1.3.4. Reel Dimensions –Type2**

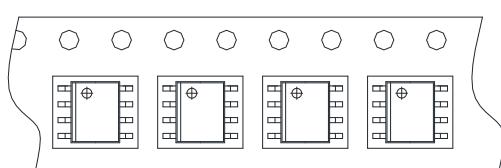
Unit : mm

**8.1.3.5. Carrier Tape Dimensions**

SYMBOLS	Reel Dimensions		Carrier Tape Dimensions									
	A	W1	A0	B0	K0	P0	P1	P2	E	F	D0	W
Spec.	330	12.5	6.50	5.20	2.10	4.00	8.00	2.00	1.75	5.50	1.50	12.00
Tolerance	+6/-3	+1.5/-0	$\pm 0.10$	$\pm 0.10$	$\pm 0.10$	$\pm 0.10$	$\pm 0.10$	$\pm 0.05$	$\pm 0.10$	$\pm 0.05$	$\pm 0.1/-0$	$\pm 0.30$

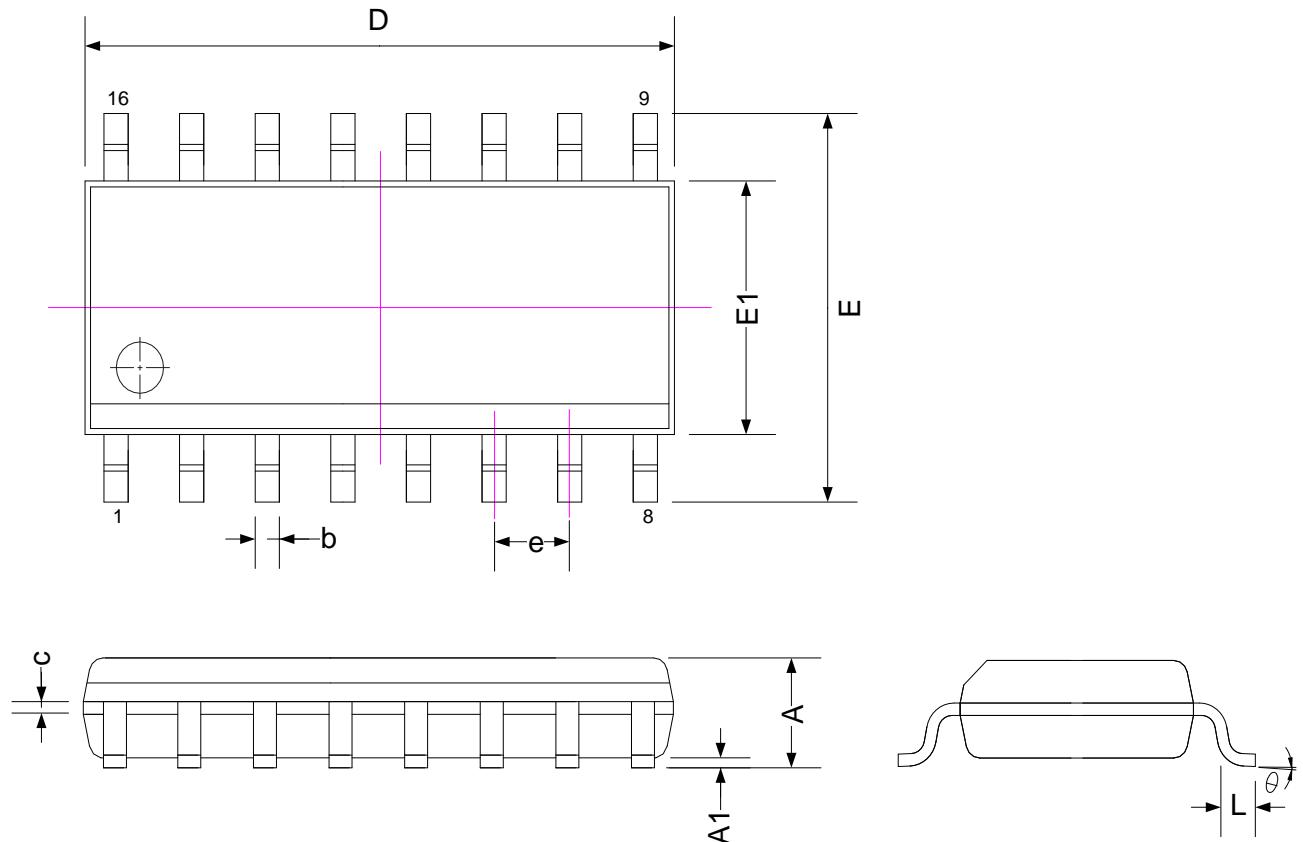
Note: 10 Sprocket hole pitch cumulative tolerance is  $\pm 0.20$ mm.

Unit : mm

**8.1.3.6. Pin1 direction**

## 8.2. SOP16(S016)

### 8.2.1. Package Dimensions SOP16(150mil)



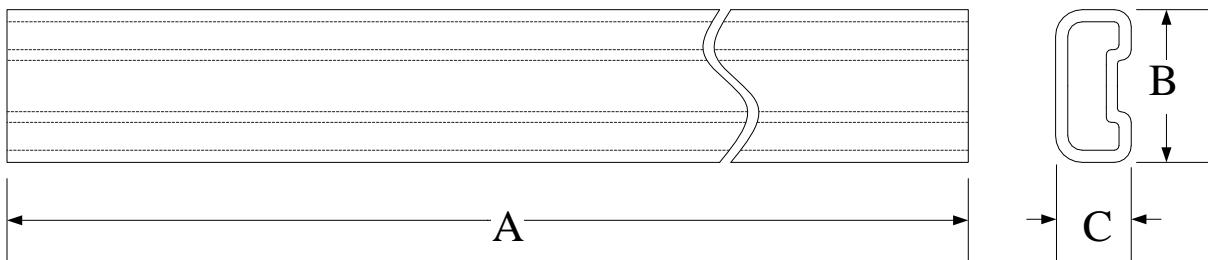
SYMBOLS	MIN	NOM	MAX
A	-	-	1.75
A1	0.10	-	0.25
b	0.31	-	0.51
c	0.10	-	0.25
D	9.90 BASIC		
E1	3.90 BASIC		
E	6.00 BASIC		
L	0.40	-	1.27
e	1.27 BASIC		
θ	0	-	8

Note :

1. All dimensions refer to JEDEC OUTLINE MS-012.
2. Do not include Mold Flash or Protrusions.
3. Unit: mm.

**8.2.2. Tube Dimensions SOP16(S016)**

Unit : mm



Type 1:

SYMBOLS	A	B	C
Spec.	521.0±1.0	7.747±0.15	3.810±0.15

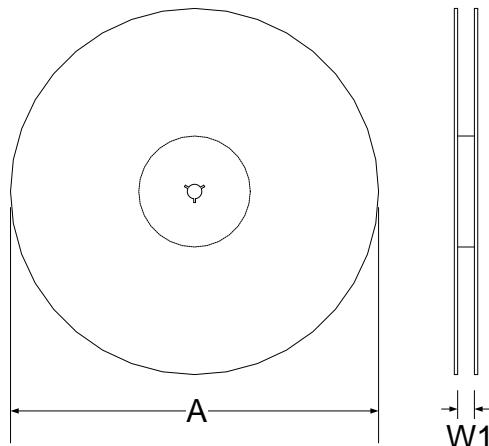
Type 2:

SYMBOLS	A	B	C
Spec.	521.0±1.0	7.874 REF.	3.810 REF.

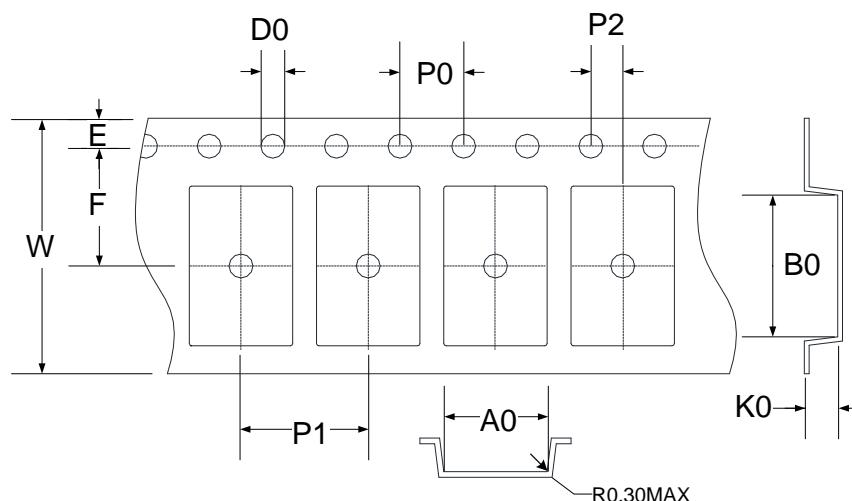
### 8.2.3. Tape & Reel Information

#### 8.2.3.1. Reel Dimensions –Type1

Unit : mm

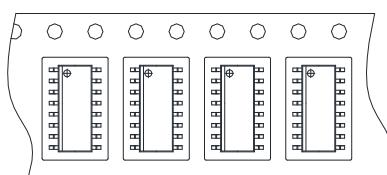


#### 8.2.3.2. Carrier Tape Dimensions



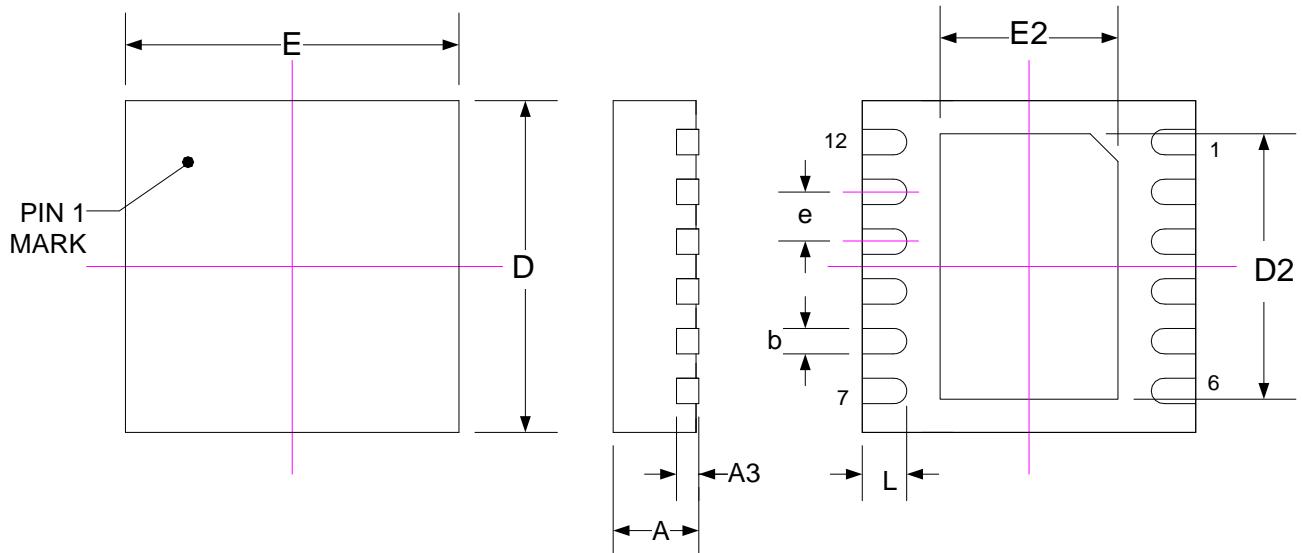
SYMBOLS	Reel Dimensions		Carrier Tape Dimensions										
	A	W1	A0	B0	K0	P0	P1	P2	E	F	D0	W	
Spec.	330	16.5	6.50	10.30	2.10	4.00	8.00	2.00	1.75	7.50	1.50	16.00	
Tolerance	+6/-3	+1.5/-0	$\pm 0.10$	$\pm 0.10$	$\pm 0.10$	$\pm 0.10$	$\pm 0.10$	$\pm 0.10$	$\pm 0.05$	$\pm 0.10$	$\pm 0.10$	+0.1/-0	$\pm 0.30$

#### 8.2.3.3. Pin1 direction



### 8.3. DFN12(AS12)

#### 8.3.1. Package Dimensions DFN12(3x3x0.75)



SYMBOLS	MIN	NOM	MAX
A	0.70	0.75	0.80
A3	0.20 REF.		
b	0.18	0.24	0.28
D	2.90	3.00	3.10
E	2.90	3.00	3.10
D2	2.25	2.40	2.55
E2	1.50	1.65	1.75
L	0.30	0.40	0.50
e	0.45 BSC		

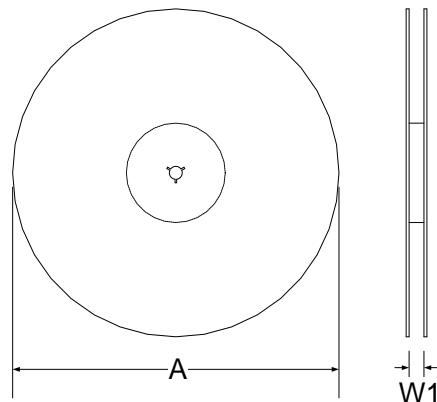
Note :

1. All dimensions refer to JEDEC OUTLINE MS-012.
2. Do not include Mold Flash or Protrusions.
3. Unit: mm.
4. [https://www.hycontek.com/hy\\_mcu/QFN\\_DFN\\_PCB\\_EN.pdf](https://www.hycontek.com/hy_mcu/QFN_DFN_PCB_EN.pdf)

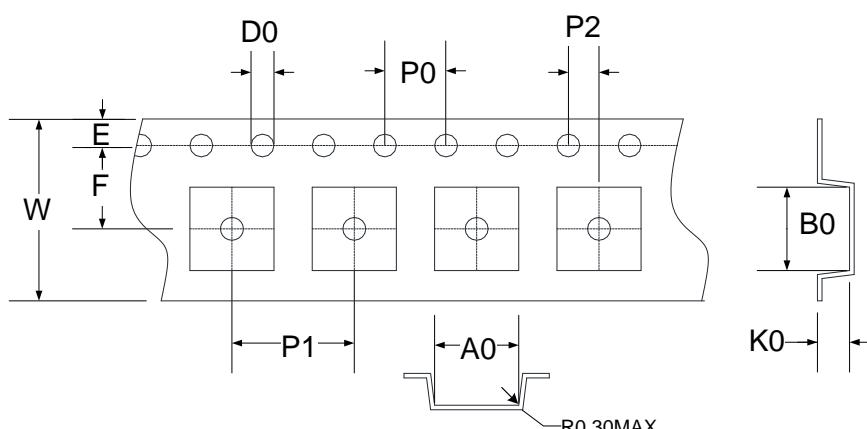
### 8.3.2. Tape & Reel Information

#### 8.3.2.1. Reel Dimensions –Type1

Unit : mm



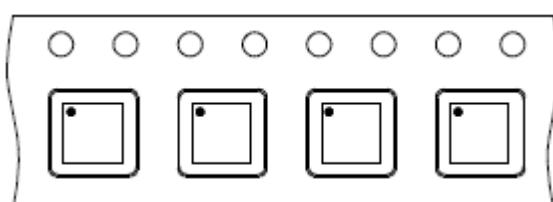
#### 8.3.2.2. Carrier Tape Dimensions



SYMBOLS	Reel Dimensions		Carrier Tape Dimensions									
	A	W1	A0	B0	K0	P0	P1	P2	E	F	D0	W
Spec.	330	12.5	3.30	3.30	1.10	4.00	8.00	2.00	1.75	5.50	1.50	12.00
Tolerance	+6/-3	+1.5/-0	$\pm 0.10$	$\pm 0.10$	$\pm 0.10$	$\pm 0.10$	$\pm 0.10$	$\pm 0.05$	$\pm 0.10$	$\pm 0.05$	$\pm 0.10$	$\pm 0.30$

Note: 10 Sprocket hole pitch cumulative tolerance is  $\pm 0.20$ mm.

#### 8.3.2.3. Pin1 direction



## 9. Revision Record

The following describes the major changes made to the document, excluding the punctuation and font changes.

Version	Page	Date	Revision Summary
V06	All	2017/11/17	First edition
	13		Update CLK block diagram
	34		Added VDD = 5V case, ENOB Table
	All		Synchronize Chinese version
V07	5	2018/01/19	Remove the Die message
	47~49		Adding DFN12 packaging information
V08	19	2018/09/20	Update Figure 4.8 GPIO block diagram
	30		Update $V_{OH}$ & $V_{OL}$ rules
V09	All	2019/03/04	Correct the description of the ADC resolution to 24-Bit ΣΔADC
	11~12		Update the Package marking information
	43,47		Update Tube Dimensions
V10	41	2022/03/18	Update the unit quantity of Tape & Reel packing type for DFN12 package